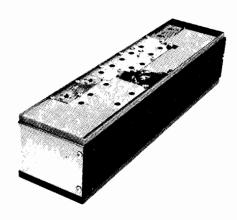


# MASTR Progress Line

25-50 MHz RECEIVER MODELS 4ER39C50-67



# **SPECIFICATIONS**

FCC Filing Designation

Frequency Range

Audio Output

Sensitivity

12-dB SINAD (EIA Method) 20-dB Quieting Method

Selectivity

EIA Two-Signal Method 20-dB Quieting Method

Spurious Response

First Oscillator Stability

Modulation Acceptance

Squelch Sensitivity

Critical Squelch Maximum Squelch

Intermodulation (EIA)

Maximum Frequency Separation

Frequency Response

ER-39-C

25-50 MHz

5 watts at less than 5% distortion

0.25 µV 0.35 µV

-85 dB (adjacent channel, 20 kHz channels) -100 dB at ±15 kHz

-100 dB

 $\pm .0005\%$  (-30°C to +60°C)

±7 kHz (narrow-band)

0.15 μV Greater than 20 dB quieting (less than 1.5  $\mu V$ )

-75 dB

0.4%

+1 and -8 dB of a standard 6-dB per octave de-emphasis curve from 300 to 3000 Hz (1000-Hz reference)

These specifications are intended primarily for the use of the serviceman. Refer to the appropriate Specification Sheet for the complete specifications.

# **TABLE OF CONTENTS**

| SPECIFICATIONS Cov   | /er  |
|--|--|
| DESCRIPTION  | 1  |
| CIRCUIT ANALYSIS   | 1  |
| RF Amplifier  1st Oscillator and Multiplier  Multiplier Selectivity Assembly  1st Mixer and Crystal Filter  2nd Oscillator, 2nd Mixer and 1st IF Amplifier  2nd IF Amplifiers and Limiters  Discriminator  Audio-Noise Amplifier  Audio Amplifiers  Squelch  Channel Guard | 1<br>2<br>2<br>2<br>2<br>3<br>3<br>3<br>3<br>4 |
| MAINTENANCE  | 5  |
| Disassembly Alignment Procedure Test Procedures  | 5<br>7<br>8                                    |
| Audio Power Output and Distortion  | 8<br>8<br>8                                    |
| Receiver Troubleshooting   | 9  |
| OUTLINE DIAGRAM  | 10   |
| SCHEMATIC DIAGRAM  | 12   |
| PARTS LIST   | 11   |
| PRODUCTION CHANGES   | 14   |
| ILLUSTRATIONS  |  |
| Figure 1 Block Diagram   | 1  |
| Figure 2 FET Nomenclature  | 2  |
| Figure 3 Removing Top Cover for Servicing  | 5  |
| Figure 4 Removing Bottom Cover for Servicing   | 5  |

## --- WARNING --

No one should be permitted to handle any portion of the equipment that is supplied with high voltage; or to connect any external apparatus to the units while the units are supplied with power. KEEP AWAY FROM LIVE CIRCUITS.

## DESCRIPTION

General Electric MASTR Progress Line Receiver Type ER-39-C is a double conversion, superheterodyne FM receiver designed for operation on the 25-50 megahertz band.

The receiver is of single-unit construction and is completely housed in a copper-plated aliminum casting for maximum shielding and rigidity. The top compartment of the casting contains the RF, oscillator, converter, and 1st IF amplifier stages. The bottom portion of the casting contains the IF-audio and squelch board, and the optional Channel Guard Board.

# **CIRCUIT ANALYSIS**

The MASTR Progress Line Receiver is completely transistorized, using silicon

transistors throughout for added reliability. Input leads to the receiver are individually filtered by the 20-pin feed-through by-pass connector J443. A regulated +10 volts is used for all receiver stages except the audio PA stage which operates from the 12-volt system supply.

Centralized metering jack J442 is provided for use with General Electric Test Set Model 4EX3A10 or 4EX8K11 for ease of alignment and servicing. The Test Set meters the oscillator, multiplier, and limiter stages as well as the discriminator and regulated 10 volts.

### RF AMPLIFIER (A341)

RF Amplifier A341 consists of two high-Q helical resonators and an RF amplifier stage (Q2). The RF signal from the antenna is coupled by RF cable W442/W443 to a tap on L341/L343/L345. The tap is

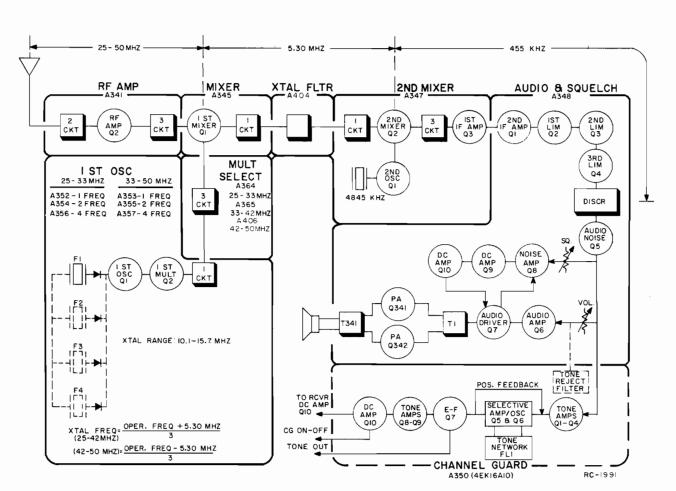


Figure 1 - Receiver Block Diagram

positioned to insure the proper impedance match to the antenna. RF energy is coupled through the two coils by an opening in the shield wall to the RF Amplifier. The coils are tuned to the incoming frequency by air trimmer capacitors C341 and C342.

The RF amplifier uses a Field-Effect Transistor (FET) as the active device. The FET may be considered a semiconductor current path (or channel) whose resistance is varied by a voltage applied between the "gate" and "source" terminals. Lead identification for the FET is shown in Figure 2. The FET has voltage-controlled characteristics, and may be compared to a vacuum tube in operation (see Figure 2).

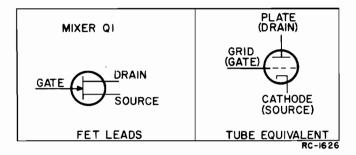


Figure 2 - FET Nomenclature

RF from the antenna is applied to the "source" terminal of FET Ql. Ql operates as a grounded-gate amplifier. This method of operation provides a low impedance input to the amplifier. The amplified output is taken from the "drain" terminal and coupled through three tuned circuits to the 1st mixer.

## 1ST OSCILLATOR AND MULTIPLIER (A352-A357)

The receiver 1st oscillator operates in a transistorized Colpitts oscillator circuit. The oscillator crystal operates in a fundamental mode at a frequency of approximately 10 to 15 megahertz. The crystal is cut to provide temperature compensation at the high end of the temperature range and is thermistor compensated at low temperatures. This provides ±.0005% frequency stability as soon as the receiver is energized—without the warm-up time required by crystal ovens or warmers.

In single frequency receivers, bias for the oscillator transistor is obtained by a jumper from Hl to H2 on the oscillator board.

In multi-frequency receivers, a diode is connected in series with the crystal, and up to three addition crystal circuits can be added. The 10-volt jumper is removed and the proper frequency is selected by switching the desired crystal circuit to

+10 volts by means of a frequency selector switch on the control unit.

Switching the +10 volts to the crystal circuit forward biases the diode and reduces its impedance. This applies the crystal frequency to the base of oscillator transistor Ql. Feedback for the oscillator is developed across C21/C22. The output is coupled to the base of 1st multiplier Q2.

The output of the 1st multiplier is transformer-coupled (T3/T4) to multiplier-selectivity assembly A364/A365. The 1st multiplier tank is tuned to three times the crystal frequency and is metered at centralized metering jack J442-4 through metering network CR1, R1, C7 and C8.

## MULTIPLIER SELECTIVITY (A364/A365/A404)

Following the 1st multiplier tank (T3/T4) are three additional L-C tuned circuits (L1, -L2 and -L3). Capacitor C34/C35/C36 couples the multiplier selectivity output to the first mixer.

## 1ST MIXER (A345) AND CRYSTAL FILTER (A404)

The 1st mixer uses a Field-Effect
Transistor (FET) as the active device
(Figure 2). The FET has several advantages
over a conventional transistor, including
a high input impedance, high power gain, and
an output that is relatively free of harmonics (low in intermodulation products).

In 1st mixer A345, RF from the 1st RF amplifier and injection voltage from the multiplier-selectivity assembly are applied to the gate of Q1. The mixer output is taken from the drain with the output tuned to the 5.3-MHz high IF frequency.

A highly selective crystal filter (A404) following the 1st mixer provides the major selectivity for the receiver. The output of the filter is fed through impedance matching transformer A347-T1 to the base of the 2nd mixer.

2ND OSCILLATOR, 2ND MIXER AND 1ST LO IF AMPLIFIER (A347)

A347-Q2 operates in a Colpitts oscillator circuit, with feedback supplied through C4. The oscillator low-side injection voltage (4845 kHz) is applied to the base of the 2nd mixer.

The high IF signal from the filter and the injection voltage from the 2nd oscillator is applied to the base of 2nd mixer Q2. The 455-kHz mixer output is applied to three tuned low IF circuits, L1, L2 and L3. These tuned circuits are required for shaping the nose of the IF waveform, and for rejecting any undesired output frequencies from the 2nd mixer.

The low IF signal is applied to the base of 1st low IF amplifier A347-Q3. The output of A347-Q3 is R-C coupled to the base of the 2nd low IF amplifier.

## 2ND LO IF AMPLIFIER AND LIMITERS (A348)

Additional amplification of the low IF signal going to the limiter stages is provided by 2nd low IF amplifier A348-Q1. This stage is metered at J442-2 through a metering network consisting of C19, CR3 and R25.

Following the 2nd low IF amplifier are three R-C coupled limiter stages (A348-Q2, -Q3 and -Q4). The 1st limiter is metered at J442-3 through metering network C20, CR4 and R26.

## DISCRIMINATOR (A348)

The limiter output is applied to a Foster-Seely type discriminator, where diodes CR1 and CR2 rectify the 455-kHz signal to recover the audio. The discriminator is metered at J442-10 through metering network C16 and R23.

## AUDIO - NOISE AMPLIFIER (A348)

The discriminator output is coupled through a low-pass filter (C16, C18, R21 and R22) to the base of audio-noise amplifier Q5. The filter removes any 455-kHz signal remaining in the discriminator output. Q5 operates as a emitter-follower to match the discriminator impedance to the VOLUME control, SQUELCH control, and Channel Guard input. The stage also provides power gain.

## AUDIO AMPLIFIERS (A348)

Any audio present in the incoming signal is coupled from the emitter of Q5 through the VOLUME control and a deemphasis network to the base of audio amplifier Q6. The de-emphasis network consists of C22, C23, R30 and R31.

Audio driver Q7 follows the audio amplifier. The audio output of Q7 is coupled through transformer T1 to provide phase inversion for the push-pull audio PA stage.

Q341 and Q342 operate as a push-pull, class AB audio PA stage. The PA output is coupled through audio transformer T341 to the loudspeaker. The yellow and white tertiary windings of T341 supply balanced feedback to the collector of Q7. The feedback winding minimizes distortion and prevents the pick-up of external electrical noise.

The PA stage provides a 5-watt output at less than 5% distortion into a 3.5-ohm load at the receiver output terminals (3.2-ohms at the Control Unit). Base bias for

the PA stage and the elimination of crossover distortion is controlled by bias adjust potentiometer R43. The potentiometer is set at the factory as shown in STEP 1 of the receiver Test Procedure.

NOTE —

Do not adjust bias adjust potentiometer R43 unless PA transistors Q341 and Q342 have been replaced.

Audio high and low are also present at centralized metering jack J442, and can be used as shown in STEP 1 of the Test Procedure.

## SQUELCH (A348)

Noise from the audio-noise amplifier operates the squelch circuit. With no carrier present in the receiver, this noise is coupled to the base of noise amplifier Q8 through a high-pass filter which attenuates frequencies below 3 kHz. The filter consists of C30, C31 and R45, as well as C34 and L3 in the collector circuit of Q8. The gain of Q8 is determined by the Squelch control, which varies the bias on the base of Q8. Thermistor RT2 keeps the critical squelch constant over wide variations in temperature.

The output of noise amplifier Q8 is rectified by diodes CR5 and CR6, and filtered by C36 and C37 to produce a negative DC voltage. This DC voltage is applied to the base of DC amplifier Q9, turning it off. When turned off, the collector voltage of Q9 rises to approximately 8 volts, turning on DC amplifier Q10. When conducting, the collector voltage of Q10 drops to almost ground potential, which removes the base bias to audio amplifier Q6 and audio driver Q7, turning them off.

When the receiver is quieted by a signal (unsquelches), the noise in the receiver is reduced, turning DC amplifier Q9 on and DC amplifier Q10 off. This allows the audio stages to conduct so that sound is heard in the speaker. A network composed of C38, CR7 and R62 slows down the switching action of Q10, preventing an obnoxious "thump" from being heard in the speaker.

Resistor R53 connects from the emitter of audio driver Q7 to the emitter of noise amplifier Q8, providing a hysteresis loop in the squelch circuit. When a weak signal opens the squelch, the signal level may be reduced by 4 to 6 dB without the squelch closing. This limits squelch "flutter" or "picket-fence" operation.

With audio driver Q7 conducting, a positive voltage through R53 helps to reduce the gain of noise amplifier Q8. This positive feedback provides a quick, positive

switching action in the squelch circuit. When the receiver squelches, audio driver Q7 turns off and its emitter potential drops to zero. This reduces the DC feedback through R53 to the emitter of noise amplifier Q8. Reducing the feedback causes Q8 to conduct harder, turning the audio stages off quickly.

Keying the transmitter removes the +10 volts from J19. This turns off DC amplifier Q9 and turns on Q10, muting the receiver.

### CHANNEL GUARD

Channel Guard Board Model 4EK16A10 is a fully transistorized encoder-decoder for use with MASTR Professional Series mobile and station combinations. The tone frequencies are controlled by plug-in tone networks that are made with precision components for excellent stability and reliability. The tone frequencies range from 71.9 to 203.5 Hz.

## Encoder (A350)

Keying the transmitter removes the receiver mute +10 volts, and forward biases feedback control diode CR5, causing it to conduct. When conducting, the diode shunts R39, R35 and C19). This provides the necessary gain to the base of Q5 to permit oscillation.

The encoder tone is provided by selective amp-oscillator transistors Q5 and Q6 which oscillate at a frequency determined by the tone network. Negative feedback applied through the tone network to the base of Q5 prevents any gain in the stage except at the desired encode frequency.

Starting network R45, C21, C22 and CR6 provide an extremely fast starting time for the encoder tone. Keying the transmitter removes the receiver mute +10 volts, causing a pulse to be applied to the base of Q6 to quickly start the oscillator. Thermistor-resistor combination R32 and RT1 provides temperature compensation for the oscillator output. Limiter diodes CR3 and CR4 keep the tone amplitude constant.

Emitter-follower Q7 follows the oscillator circuit. The encoder tone is taken from the emitter of Q7 and applied to the transmitter.

## Decoder (A350)

The decoder function is designed to eliminate all calls that are not tone coded for the Channel Guard Frequency. As long as the CHANNEL GUARD-OFF switch on the control unit is left in the CHANNEL GUARD position, all signals are locked out except those from transmitters that are continuously tone coded for positive identification by the receiver.

Placing the CHANNEL GUARD-OFF switch in the OFF position instantly disables the Channel Guard operation so that all calls on the channel can be heard. When the hookswitch option is used, lifting the microphone from its hanger disables the Channel Guard Circuit.

Audio, tone and noise are taken from the emitter of the receiver audio-noise amplifier Q348-Q5 and is fed through A350-J1 to four tone amplifier and bandpass filter circuits. The filters remove the audio and high-frequency noise from the signal, and the tone amplifiers provide sufficient gain to insure clipping by limiter diodes CR1 and CR2. The clipping action eliminates variation in the squelch performance due to changes in tone deviation. The signal is then applied to selective amplifiers Q5 and Q6 which amplify only the tone determined by the tone network.

The output of the selective amplifier is applied through emitter-follower Q7 to the high gain, broad-band tone amplifiers Q8 and Q9. The output of Q9 is rectified by detector diodes CR7 and CR8, and the resulting negative DC voltage controls the squelch gate. Q8 is normally biased for low gain. When the tone is detected by CR7 and CR8, feedback is provided through R54 to quickly change the bias on Q8 for full gain. This ensures a more positive "unsquelching" action.

Squelch gate diode CR9 is normally forward biased by a positive DC voltage (approximately 1.5 volts) fed through R58. The forward bias causes CR9 to conduct, feeding a DC voltage to the base of DC amplifier A348-Q10 in the receiver. This removes the bias on the receiver audio stages and holds them off.

When the proper tone is applied to the decoder, the negative DC voltage from the detector diodes back-biases squelch gate diode CR9 and cuts off the positive bias to the receiver DC amplifier A348-Q10. However, the receiver noise squelch circuit continues to operate until a carrier quiets the receiver.

Placing the CHANNEL GUARD - OFF switch in the OFF position (or removing the microphone from its hookswitch) removes the ground to the base of the decoder DC switch (Q10), causing it to conduct. This backbiases squelch control diode CR9 and cuts off the positive bias to the receiver DC amplifier (A348-Q10). The receiver noise squelch circuit continues to operate until a carrier quiets the receiver.

A tone rejection filter connected in parallel with A348-J12 (in the receiver) bypasses any incoming tone to ground. This attenuates the tone level reaching the receiver audio circuits. The filter is composed of C26, C27, C28, C29, L1 and R59.

An optional tone reject filter (A402) that is identical to the filter described above is available for use in two-way radios with transmitter Channel Guard only.

# **MAINTENANCE**

## DISASSEMBLY

To service the receiver from the top--

- Pull locking handle down and pull radio about one inch out of mounting frame.
- 2. Pry up cover at rear of receiver.
- 3. Slide cover back and lift off.

- Pull locking handle down. Pull radio out of mounting frame.
- Remove screws in bottom cover. Pry up cover at back of receiver.
- 3. Slide cover back and lift off.

To remove the receiver from the system frame--

- Loosen the two Phillips-head retaining screws in from casting (see Figure 3), and pull casting away from system frame.
- Remove the four screws in the back cover.
- Remove the two screws holding the receiver at each end of the system frame.
- Disconnect the antenna jack and the 20-pin connector from the front of the receiver, and slide the unit out of the system frame.

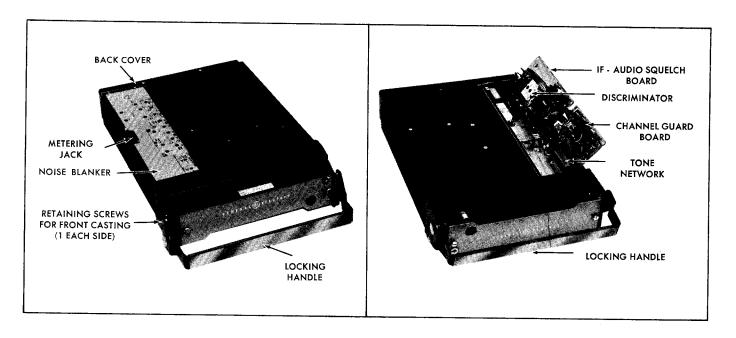


Figure 3 - Removing Top Cover

Figure 4 - Removing Bottom Cover

# FRONT END ALIGNMENT

# EQUIPMENT REQUIRED

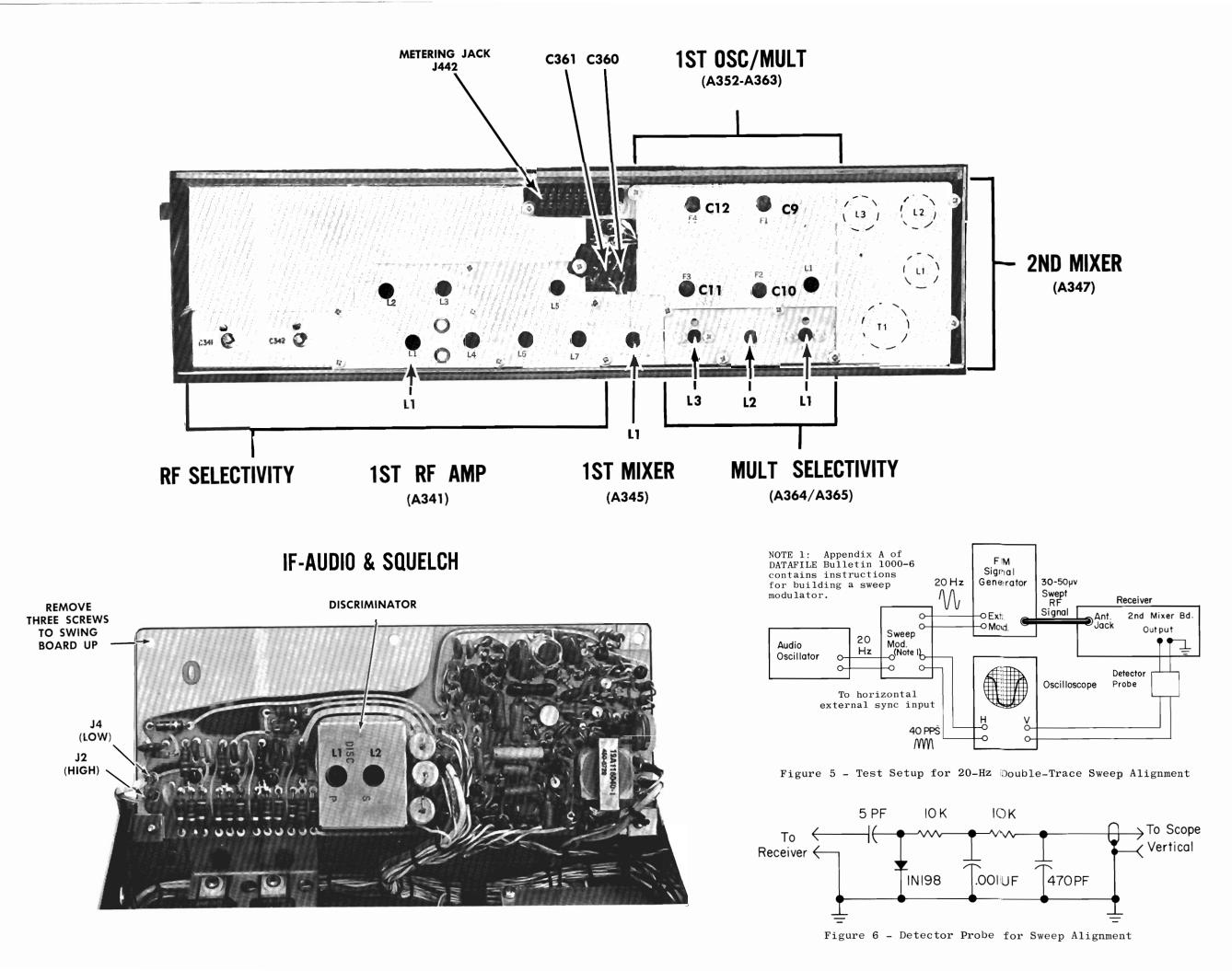
- 1. GE Test Set Models 4EX3A10, 4EX8K10, 11 (or 20,000 ohms-per-volt Multimeter with a 1-volt scale).
- 2. A 455 kHz and 25-50 MHz signal source. Connect a one-inch piece of insulated wire no larger than .065-inch diameter to generator output probe.

## PRILIMINARY CHECKS AND ADJUSTMENTS

- 1. Connect Test Set to Receiver Centralized Metering Jack J442 and set meter sensitivity switch to the TEST 1 position (or 1-volt position on 4EX8K10, 11).
- 2. With Test Set in Position J, check for regulated +10 volts. If using Multimeter, measure from C360 to C361.
- 3. If using Multimeter, connect the positive lead to J442-16 (Ground).
- Disable Channel Guard.

### ALIGNMENT PROCEDURE

|      | METERI               | NG POSITION             |  |                    |  |
|------|----------------------|-------------------------|--|--------------------|--|
| STEP | GE Test<br>Set       | Multimeter<br>- at J442 | TUNING CONTROL   | METER<br>READING   | PROCEDURE  |
|      |                      |                         | OSCILLATOR/MU  | LTIPLIER           |  |
| 1.   | D<br>(MULT-1)        | Pin 4                   | L4 (on 1st OSC/MULT)<br>and L1, L2 (on MULT<br>SELECTIVITY)        | See Pro-<br>cedure | Tune L4 on 1st OSC/MULT and<br>L1 on MULT SELECTIVITY for<br>maximum meter reading. Then<br>tune L2 for minimum meter<br>reading. Change voltage scale<br>if necessary. Repeat this step   |
|      |                      |                         | RF AMPLIFIER &   | SELECTIVITY        |  |
| 2.   | A (DISC)             | Pín 10                  |  | Zero               | Apply an on-frequency signal adjacent to L7. Adjust the signal generator for discriminator zero.   |
| 3.   | B<br>(2nd IF<br>Amp) | Pin 2                   | L1 (1st RF Amp),<br>L6, L7, C341 and<br>C342 (RF SELEC-<br>TIVITY) | Maximum            | Apply an on-frequency signal to the antenna jack, keeping below saturation. Tune L1, L6, L7, C341, and C342 for maximum meter reading.   |
| 4.   | .,                   | ,,                      | L4 (1st OSC/MULT)<br>L1, L2 and L3<br>(MULT SELECTIVITY)           | Maximum            | Apply an on-frequency signal as above, keeping below saturation. Tune L4 on 1st OSC/MULT and L1, L2 and L3 on MULT SELECTIVITY for maximum meter reading.  |
|      | 1                    |                         | FREQUENCY AD   | JUSTMENT           |  |
| 5.   | 5. A Pin 10 (DISC)   |                         | C9 on 1st OSC<br>(C10, C11 or<br>C12 for multi-<br>frequency)      | Zero               | Apply an on-frequency signal to the antenna jack. Tune C9 for zero discriminator reading In multi-frequency units, tune C10, C11 or C12 as required.   |
|      |                      |                         |  |                    | For proper frequency control of the receiver, it is recommended that all frequency adjustments be made when the equipment is at a temperature of approximately 75°F. In no case should frequency adjustments be made when the equipment is outside the temperature rang of 50° to 90° F. |



### EQUIPMENT REQUIRED

# **COMPLETE RECEIVER ALIGNMENT**

- 1. GE Test Set Models 4EX3A10, 4EX8K10, 11 (or 20,000 ohms-per-volt Multimeter with a 1-volt scale).
- 2. A 455-kHz signal source (GE Test Set Model 4EX7A10) and 25-50 MHz signal source. Connect a one-inch piece of insulated wire no larger than .065-inch diameter to generator output prove.

## PRELIMINARY CHECKS AND ADJUSTMENTS

- 1. Connect Test Set to Receiver Centralized Metering Jack J442, and set meter sensitivity switch to the TEST | position (or 1-volt position on 4EX8K10, 11).
- 2. For large changes in frequency or a badly misaligned receiver, set crystal trimmer C9 to mid-capacity. In multi-frequency receivers, set C10, C11 or C12 to mid-capacity as required. Where the maximum frequency spacing is less than 100 kHz, align the unit on channel F1. If the frequency spacing is greater than 100 kHz, align the receiver on the center frequency.
- 3. With Test Set in Position J, check for regulated +10 volts. If using Multimeter, measure from C360 to C361.
- 4. If using Multimeter, connect the positive lead to J442-16 (Ground).
- 5. Disable the Channel Guard.

### ALIGNMENT PROCEDURE

|       | METERING             | POSITION                |  |                    |  | -  |
|-------|----------------------|-------------------------|--|--------------------|--|--|
| STEP  | GE Test Set          | Multimeter<br>- at J442 | TUNING CONTROL   | METER<br>READING   | PROCEDURE  |  |
|       |                      |                         | DISCE  | RIMINATOR &        | OSCILLATOR   | _  |
| 1.    | A<br>(DISC)          | Pin 10                  | Ll and L2 (on IF-AUDIO<br>SQUELCH board)                         | Zero               | Remove three screws and swing open the IF-AUDIO<br>Adjust L1 (disc primary) 1/2 turn counterclockwi<br>coil. Next, apply a 455-kHz signal to J2 and J4<br>secondary) for zero meter reading. | se from the bottom of<br>and adjust L2 (disc |
| 2.    | A<br>(DISC)          | Pin 10                  |  | See Pro-<br>cedure | Alternately apply a 450-kHz and 460-kHz signal an of at least 0.3 volt, but not more than 0.5 volt readings must be within .05 volt. Do not attempt closer than .05 volt.                    | on GE Test Set. Both                         |
| 3.    | D<br>(MULT-1)        | Pin 4                   | L4 (on 1st OSC/MULT)<br>and L1, L2 & L3 (on<br>MULT SELECTIVITY) | See Pro-<br>cedure | Tune L4 on 1st OSC/MULT and L1 on MULT SELECTIVI reading. Tune L2 for minimum meter reading. Ch necessary. Then tune L3 for maximum meter readi  | ange voltage scale if                        |
|       |                      |                         | RF AM  | MPLIFIER &         | SELECTIVITY  |  |
| 4.    | A<br>(DISC)          | Pin 10                  |  | Zero               | Apply an on-frequency signal adjacent to L7. Adgenerator for discriminator zero.   | just the signal                              |
| 5.    | B<br>(2nd IF<br>AMP) | Pin 2                   | L7 and L6 (RF<br>SELECTIVITY)                                    | Maximum            | Apply an on-frequency signal and tune for maximu shown below, keeping signal below saturation.   | m meter reading as                           |
|       | ,                    |                         |  |                    | Apply Signal Generator Probe to:   | Tune:  |
|       |                      |                         |  |                    | L6 ,   | L7   |
|       |                      |                         |  |                    | L1   | 1.6  |
| 6.    | "                    | "                       | C341, C342 and L1<br>(1st RF Amp)                                | Maximum            | Apply an on-frequency signal to the antenna jack and L1 for maximum meter reading, keeping signal  | . Tune C341, C342, below saturation.         |
| 7.    | "                    |                         | L1 (1st RF Amp)<br>L6, L7, C341, and<br>C342 (RF SELECTIVITY)    | Maximum            | Apply an on-frequency signal as above, keeping b<br>Tune L1, L6, L7, C341 and C342 for maximum meter   |  |
| 8.    | "                    | "                       | L3 (MULT SELECTIVITY)  | Maximum            | Apply on-frequency signal as above, keeping belo L2 & L3 (on MULT SELECTIVITY) for maximum meter 1   |  |
|       |                      |                         |  | 2ND MI             | XER & LO IF  |  |
| ecess | ary, use the         | procedure out           | lined in STEPS 9, 10, and 11.<br>ring IF trace on oscilloscope.  | Ll (on l           | ory and will normally require no further adjustmen<br>st mixer) provides impedance matching for the crys   | stal filter input and                        |
|       |                      |                         |  | — NOTE —           | _  |  |
|       |                      |                         | BULLETIN 1000-6 (IF Alignment<br>Alignment is required.          | of Two-Way         | 7 Radio FM Receivers) for helpful suggestions on ho  | ow to  |
|       |                      |                         |  | T                  |  |  |
| 9.    | (2nd IF<br>AMP)      | Pin 2                   | A 347-L3, L2, L1, T1 (2nd Mixer)                                 | Maximum            | Apply on-frequency, unmodulated signal and tune<br>T1 for maximum meter reading, keeping signal bel  |  |
| 10    |                      |                         | 4247 12 19 11 T1 (2md  | 1                  | Connect come minus language and detector on  | about in Figure 4                            |

# Connect scope, signal generator, and detector as shown in Figure 4. Set signal generator level for 30-50 µv and modulate with 10 kHz at 20 Hz. With detector at the collector of A347-Q3 (2nd mixer board output), tune L3, L2, L1, T1 (2nd Mixer) and L1 (1st Mixer) for double race as shown on scope pattern. See Pro- Check to see that discriminator idling voltage is within ±.05 volt of zero with no signal applied. Check to see that modulation acceptance bandwidth is between ±7 and 9 kHz.

C9 on 1st OSC (C10, Cll or Cl2 for

FREQUENCY ADJUSTMENT

NOTE

For proper frequency control of the receiver, it is recommended that all frequency adjustments be made when the equipment is at a tem be attraction and the state of approximately 75°F. In no case should frequency adjustments be made when the equipment is outside the temperature range of 50° to 90°F.

# **ALIGNMENT PROCEDURE** Apply an on-frequency signal to the antenna jack. Tune C9 for zero discriminator reading. In multi-frequency units, tune C10, C11 or C12

25—50 MHz MASTR RECEIVER MODELS 4ER39C50-67

Issue 1

LBI-4123

# TEST PROCEDURES

These Test Procedures are designed to help you to service a receiver that is operating——but not properly. The problems encountered could be low power, poor sensitivity, distortion, limiter not operating properly, and low gain. By following the sequence of test steps starting with Step 1, the defect can be quickly localized. Once

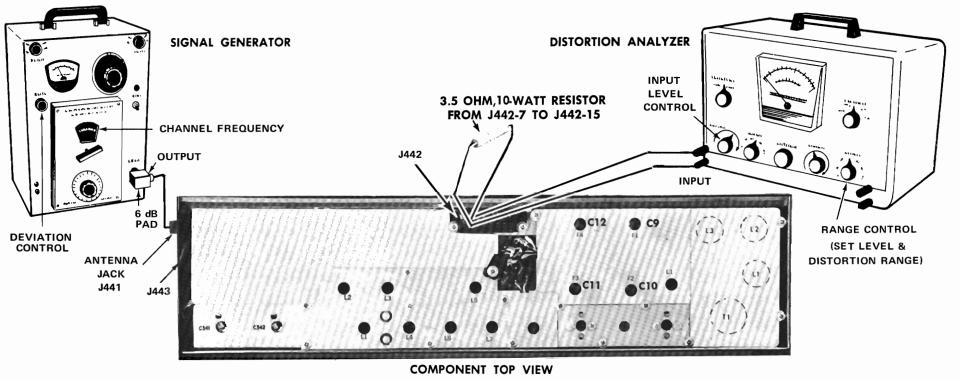
the defective stage is pin-pointed, refer to the "Service Check" listed to correct the problem. Additional corrective measures are included in the Troubleshooting Procedure. Before starting with the Receiver Test Procedures, be sure the receiver is tuned and aligned to the proper operating frequency.

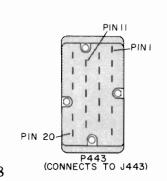
# TEST EQUIPMENT REQUIRED

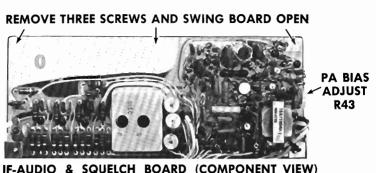
- Distortion Analyzer similar to: Heath IM-12
- Signal Generator similar to:
   Measurements M-560
- 6-dB attenuation pad, and 3.5-ohm, 10-watt resistor

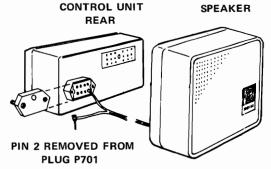
# PRELIMINARY ADJUSTMENTS

- 1. Connect the test equipment to the receiver as shown for all steps of the receiver Test Procedure.
- 2. Turn the SQUELCH control fully clockwise for all steps of the Test Procedure.
- 3. Turn on all of the equipment and let it warm up for 20 minutes.









# STEP 1 AUDIO POWER OUTPUT AND DISTORTION

# TEST PROCEDURE

Measure Audio Power Output as follows:

- A. Apply a 1,000-microvolt, on-frequency test signal modulated by 1,000 hertz with ±3.0 kHz deviation to antenna jack J441.
- B. With Five-Watt Speaker:

Disconnect speaker lead pin from J701-2 (on rear of Control Unit).

Connect a 3.5-ohm load resistor from J442-15 to J442-7. Connect the Distortion Analyzer input across the resistor as shown.

OF

# With Handset:

Lift the handset off of the hookswitch. Connect the Distortion Analyzer input from J442-15 to J442-7.

- C. Adjust the VOLUME control for five-watt output (4.18 VRMS using the Distortion Analyzer as a VTVM).
- . Make distortion measurements according to manufacturer's instructions. Reading should be less than 5%. If the receiver sensitivity is to be measured, leave all controls and equipment as they are.

# SERVICE CHECK

If the distortion is more than 5%, or maximum audio output is less than five watts, make the following checks:

- E. Battery and regulator voltage---low voltage will cause distortion. (Refer to Receiver Schematic Diagram for voltages.)
- F. P.A. Bias Adjust (R43) -- Turn the SQUELCH control fully counterclockwise.

Then connect a milliammeter in series with the +12 volt lead at P443-11. With no signal in, adjust R43 for a reading of approximately 20 milliamps. This adjustment should not be necessary unless an output transistor has been rereplaced.

- Audio Gain (Refer to Receiver Trouble-shooting Procedure).
- H. Discriminator Alignment (Refer to Receiver Alignment on reverse side of page).

# STEP 2 USABLE SENSITIVITY (12-dB SINAD)

If STEP 1 checks out properly, measure the receiver sensitivity as follows:

- A. Apply a 1000-microvolt, on frequency signal modulated by 1000 Hz with 3.0-kHz deviation to J441.
- Place the RANGE switch on the Distortion Analyzer in the 200 to 2000-Hz distortion range position (1000-Hz filter in the circuit). Tune the filter for minimum reading or null on the lowest possible scale (100%, 30%, etc.)
- C. Place the RANGE switch to the SET LEVEL position (filter out of the circuit) and adjust the input LEVEL control for a +2 dB reading on a mid range (30%).
- . While reducing the signal generator output, switch the RANGE control from SET LEVEL to the distortion range until a 12-dB difference (+2 dB to -10 dB) is obtained between the SET LEVEL and distortion range positions (filter out and filter in).
- E. The 12-dB difference (Signal plus Noise and Distortion to noise plus distortion ratio) is the "usable" sensitivity level. The sensitivity should be less than 0.25 microvolts with an audio output of at least 2.5 watts (2.9 volts RMS across the 3.5-ohm receiver load using the Distortion Analyzer as a VTVM).

F. Leave all controls as they are and all equipment connected if the Modulation Acceptance Bandwidth test is to be performed.

# SERVICE CHECK

If the sensitivity level is more than 0.25 microvolts, check the alignment of the RF stages as directed in the Alignment Procedure, and make the gain measurements as shown on the Troubleshooting Procedure.

# STEP 3 MODULATION ACCEPTANCE BANDWIDTH (IF BANDWIDTH)

If STEPS 1 and 2 check out properly, measure the bandwidth as follows:

- A. Set the Signal Generator output for twice the microvolt reading obtained in the 12-dB SINAD measurement.
- B. Set the RANGE control on the Distortion Analyzer in the SET LEVEL position (1000-Hz filter out of the circuit), and adjust the input LEVEL control for a +2 dB reading on the 30% range.
- While increasing the deviation of the Signal Generator, switch the RANGE control from SET LEVEL to distortion range until a 12-dB difference is obtained between the SET LEVEL and distortion range readings (from +2 dB to -10 dB).
- The deviation control reading for the 12-dB difference is the Modulation Acceptance Bandwidth of the receiver. It should be more than ±7 kHz (but less than ±9 kHz).

# SERVICE CHECK

If the Modulation Acceptance Bandwidth test does not indicate the proper width, make gain measurements as shown on the Receiver Troubleshooting Procedure.

| Metering Position  | Reading With<br>No Signal In | Reading with 1 Micro-<br>volt Unmodulated |
|--------------------|------------------------------|---|
| A (Disc Idling)    | Less then ±.05 VDC           |   |
| B (2nd IF)         | .03 VDC                      | 0.2 VDC                                   |
| C (1st Lim)        | 0.5 VDC                      | 0.8 VDC                                   |
| D (Mult-1)         | 0.6 VDC                      |   |
| J (Reg. +10 volts) | +10 VDC                      |   |

# **SYMPTOM CHECKS**

| SYMPTOM                                     | PROCEDURE  |
|---|--|
| NO SUPPLY VOLTAGE                           | <ul> <li>Check power connections and continuity of supply<br/>leads, and check fuse in power supply. If fuse is<br/>blown, check receiver for short circuits.</li> </ul> |
| NO REGULATED 10-VOLTS                       | <ul> <li>Check the 12-volt supply. Then check regulator<br/>circuit. (See Troubleshooting Procedure for Power<br/>Supply).</li> </ul>                                    |
| LOW 1ST LIM READING                         | • Check supply voltages and then check oscillator reading at J442-4 & 5 as shown in STEP 2A.   |
|   | • Make SIMPLIFIED VTVM GAIN CHECKS from 2nd Mixer through 1st Limiter stages as shown in STEP 2A.  |
| LOW OSCILLATOR/MULTI-<br>PLIER READINGS     | • Check alignment of Oscillator, (Refer to Front End Alignment Procedure).   |
|   | • Check voltage readings of 1st Oscillator/Multi-<br>plier Q1/Q2.  |
|   | • Check crystal Yl.  |
| LOW RECEIVER SENSITIV-                      | • Check Front End Alignment. (Refer to Receiver Alignment Procedure).  |
|   | • Check antenna connections, cable and relay.  |
|   | • Check 1st and 2nd Oscillator injection voltage.  |
|   | • Check voltage readings of 1st Mixer, HI IF Amp and 2nd Mixer.  |
|   | • Make SIMPLIFIED GAIN CHECKS (STEP 2A).   |
| LOW AUDIO                                   | • Check Audio PA (Q341 & Q342) voltage readings on schematic diagram.  |
|   | <ul> <li>Make simplified gain and waveform checks of<br/>audio and squelch stages. (Steps 2A and 2B).</li> </ul>   |
|   | • Make unsquelched voltage readings in Audio section. (Refer to Receiver Schematic Diagram).   |
|   | • Check voltage readings on Channel Guard board.   |
| HIGH DISTORTION AT LOW AUDIO LEVELS (50 MW) | • Set PA bias adjust R43 as specified under Service Checks in STEP 1 of TEST PROCEDURES.   |
| IMPROPER SQUELCH OPERATION                  | <ul> <li>Check voltage readings of Squelch circuit.<br/>(Refer to Receiver Schematic Diagram).</li> </ul>  |
|   | <ul> <li>Make gain and waveform checks of audio and<br/>squelch stages. (Steps 2A and 2B).</li> </ul>  |
| DISTORTION IDLING TOO<br>FAR OFF ZERO       | <ul> <li>See if discriminator zero is in center of IF<br/>bandpass.</li> </ul>   |

# STEP 3-VOLTAGE RATIO READINGS

## EQUIPMENT REQUIRED:

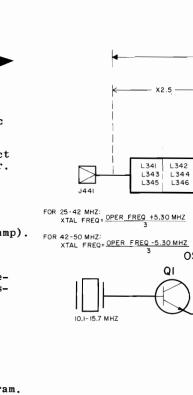
- RF Voltmeter (similar to Boonton Model 91-CA or Millivac Type MV-18 C.
- Signal on receiver frequency (below saturation). Correct frequency can be determined by zeroing the discriminator. Use 1,000 hertz signal with 3.3 kHz deviation.

## PROCEDURE:

- 1. Apply probe to input of stage (for example, base of RF amp). Peak resonant circuit of stage being measured and take voltage reading (E $_1$ ). OS
- 2. Move probe to input of following stage (1st mixer\*). Repeak first resonant circuit then peak circuit being measured and take reading (E2).
- 3. Convert readings by means of the following formula.

Voltage Ratio = 
$$\frac{E_2}{E_1}$$

4. Check results with typical voltage ratios shown on diagram.



# STEP 2A-SIMPLIFIED VTVM GAIN CHECKS —— SIGNAL GENERATOR INPUT AT J441 MAINTAIN STANGAT DISCRIMINATOR ZERO SIGNAL GENERATOR INPUT AT J441 MAINTAIN STANGAT DISCRIMINATOR ZERO

IST MIXER

# 1. VTVM - AC & DC

EQUIPMENT REQUIRED:

2. Signal generator (Measurements M560 to equivalent).

# PRELIMINARY STEPS:

- Set VOLUME control for 4.18 volts across 3.5-ohm load. If this cannot be obtained, set to approx. 70% of max. rotation.
- Set SQUELCH control fully counterclockwise.
- 3. Receiver should be properly aligned.
- 4. Connect VTVM between system negative and points indicated by arrow.

| L2          | TILER A346   | IZ5 MV<br>INJECTION<br>VOLTAGE                      |  |  |  |   | 2ND IF METER               | IST LIN | ) <u> </u>              |   | LI BL2          | DISC METER   |                          | VOL HILL   | DE-EMPHASIS<br>NET  |                   | <del>-</del>    | TI   |                 | T341   | <b>-</b> [[]    |
|-------------|--|---|--|--|--|---|----------------------------|---------|-------------------------|---|-----------------|--|--------------------------|--|---|-------------------|-----------------|--|-----------------|--|-----------------|
| SELECTIVITY | ** SHORT 2ND OSC B   | MOVE CRYSTAL BEFORE VOLTAGE. REPLACE SURE COLLECTOR |  |  |  |   | J442-2                     | J442-3  |                         |   | /               | J442-10  | / / L NO                 | VOLUME CONTROL (SET FOR 4.18V RMS OR 5 WATTS ACROSS DC 3.5 \( \text{LOAD} \) AT SPEAK  NOISE USE SEE SEE SEE SEE SEE SEE SEE SEE S | L   |                   | DC AG           | AMP<br>Pilo  |                 | J442-7   | DIO PUT J442-15 |
|             | *** REMOVE SHORT O<br>INPUT SIGNAL LE<br>TO OVERRIDE INJ                       | VEL TO APPROX IMV ECTION VOLTAGE.                   |  |  |  |   |                            |         |                         |   |                 |  | /<br>-<br>-              | -IO VDC SQUELCH CONTROL (FULLY COUNTER- CLOCK WISE)  |   | -IO VDC           |                 |  |                 |  |                 |
|             | SIGNAL GENERATOR<br>INPUT AT J441<br>MAINTAIN SETTING AT<br>DISCRIMINATOR ZERO |   | UNMODULATED  | UNMODUL ATED   | UNMODULATED  | UNMODUJLATED  | I MICROVOLT<br>UNMODULATED | NO SIGN | NAL INPUT MI            | TANDARD SIGNAL-(I<br>ILLIVOLT AT RCVR FREQ<br>ODULATED BY IKHZ    | STANDARD SIGNAL | STANDARD SIGNAL  | STANDARD SIGNAL          | STANDARD SIGNAL  | STANDARD SIGNAL   | STANDARD SIGNAL   | STANDARD SIGNAL | STANDARD SIGNAL  | STANDARD SIGNAL | STANDARD SIGNAL  |                 |
|             | PROCEDURE  |   | INCREASE GENERA-<br>OUTPUT UNTIL VTVM<br>READING ON 1.5 V<br>SCALE DECREASES<br>BY 50 MV | INCREASE SIGNAL GENERATOR OUTPUT FROM ZERO UNTIL VTVM READING DE- CREASES BY 5 % | INCREASE SIGNAL GENERATOR OUTPUT FROM ZERO UNTIL VTVM READING DE- CREASES BY 5 % | INCREASE SIGNAL GENERATOR OUTPUT FROM ZERGO UNTIL VTVM READING DE- CREASES BY 5 % | -                          |         | W                       | TH 3.3 KHZ DEVIATION)   |                 |  |                          |  |   |                   |                 |  |                 | CONNECT VTVM OR SCOPE<br>ACROSS 3.5 \( \O \text{LOAD} \) BETWEEN<br>J442-7 AND J442-15 WITH<br>SPEAKER DISCONNECTED. |                 |
|             | READING  | 2.4 VDC   | GENERATOR OUTPUT<br>SHOULD BE APPROX<br>20 MILLIVOLTS                                    | GENERATOR OUTPUT<br>SHOULD BE APPROX<br>600 MICROVOLTS                           | GENERATOR OUTPUT<br>SHOULD BE APPROX<br>5 MICROVOLTS                             | GENERATOR: OUTPUT<br>SHOULD BE: APPROX<br>O.3 MICROVOLTS                          |                            | - 2 V   | DC                      | 0.8 VAC   | 0.75 VAC        | 0.55 VAC   | 0.15 VAC                 | 2.3 VAC  | 0.05 VAC  |                   | O.5 VAC         | I.4 VAC  | IO VAC          | 4.18 VAC   |                 |
| ,           |  |   |  |  |  |   |                            | _       |                         |   |                 |  |                          |  |   |                   |                 |  |                 |  |                 |
|             |  |   |  |  |  |   |                            |         | SCOPE SET               | TTING   | O.5 MS/DIV      | 0.5 MS/DIV   | 0.5 MS/DIV               | O.5 MS/DIV   | O.5 MS/DIV  | 0.5 MS/DIV        | 0.5 MS/DIV      | 0.5 MS/DIV   | 0.5 MS/DIV      | 0.5 MS/DIV   |                 |
|             |  |   |  |  |  |   |                            |         |                         |   | I VOLT/DIV      | I VOLT/DIV   | I VOLT/DIV IV P-P(NOISE) | 2 VOLTS/DIV  | 0.5 VOLTS/DIV   | 50 MILLIVOLTS/DIV | I VOLT/DIV      | 2 VOLTS/DIV  | IO VOLTS/DIV    | 5 VOLTS/DIV  |                 |
|             |  |   |  |  |  |   |                            |         | (I MILLIVOL<br>MODULATE | ARD SIGNAL<br>T AT RECEIVER FREQ<br>ED BY IKHZ WITH<br>DEVIATION) |                 |  | IV F-F (NOISE)           | 5.7 V P-P (NOISE)  | 3 V P-P (NOISE)   | 0.1 V P-P         | 1.9 V P-P       | 4 V P-P  | 30 V P-P        | IZ V P-P   |                 |
|             |  | STEP 2  | 2B-AUDIC   | ) & SQU  | ELCH WA  | VEFORM  | ns <del></del>             | -       | NOISE<br>(NO SIGNA      | WAVE FORM   | pill appear     | A PARTY OF THE STATE OF THE STA |                          | White the second section   | Hanna de la composition della | Mappayile         | Surprise Co     | No de la composição de la | 4-11-7          | de production  |                 |

(RC-1992)

AUDIO/NOISE

AUDIO DRIVER

# EQUIPMENT REQUIRED:

Oscilloscope.

2. Signal generator (measurements M560 to equivalent).

# PRELIMINARY STEPS:

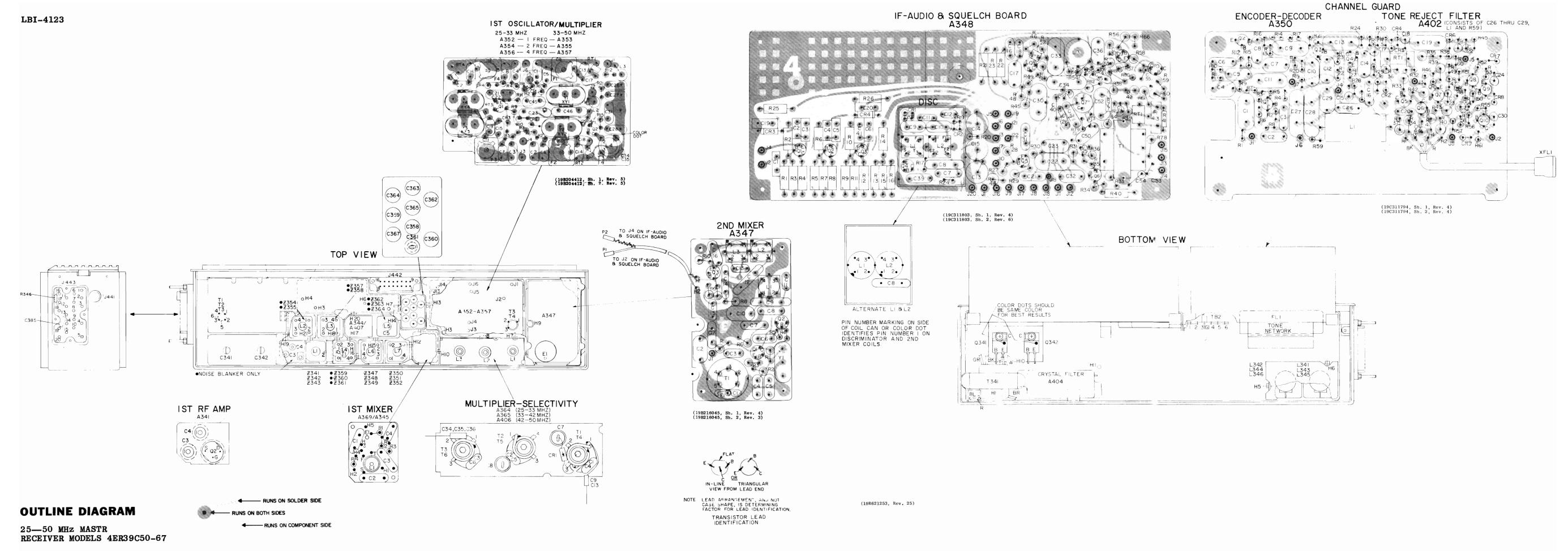
- Set VOLUME control for 4.18 volts across 3.5-ohm load. If this cannot be obtained, set to approx. 70% of max. rotation.
- 2. Set SQUELCH control fully counterclockwise.
- 3. Receiver should be properly aligned.
- Connect oscilloscope between system negative and points indicated by arrow.

# TROUBLESHOOTING PROCEDURE

AUDIO PA Q341/Q342

25—50 MHz MASTR RECEIVER MODELS 4ER39C50-67

Issue 1



10

| P     | ART  | S LIST     |  |
|-------|------|------------|--|
| 1     | LBI- | 4127G      |  |
| 25-50 | MHz  | RECE I VER |  |

MODELS 4ER39C50 - 4ER39C67 SYMBOL | GE PART NO. DESCRIPTION - - - - - - - CAPACITORS - - - - - - -Ceramic, feed-thru: 1000 pf +100%-0%, 500 VDCW; sim to Allen-Bradley Type FA5C. Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap. 5494481P11 L1 7491382P101 Coil, RF: 100  $\mu h$   $\pm 10\%$ , 4 ohms DC res max; sim to Delevan 3500 Series. N Type, field effect; sim to Type 2N4416. Q2\* 19A116960P1 N Channel; sim to T1S34. 3R152P470J Composition: 47 ohms ±5%, 1/4 w. R11 3R152P101J and R12 Composition: 100 ohms ±5%, 1/4 w. ----- SOCKETS -----A345 C4 5494481P111 Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap. Ceramic disc: 1000 pf  $\pm 20\%$ , 1000 VDCW; sim to RMC Type JF Discap. C5 5494481P11 L1 19B216880G1 Composition: 51,000 ohms ±5%, 1/4 w. 3R152P513J Composition: 3300 ohms ±10%, 1/4 w. 3R152P332K Composition: 100 ohms  $\pm 10\%$ , 1/4 w. 3R152P101K ----- TRANSISTORS -----Q1\* 19A116960P1 N Type, field effect; sim to Type 2N4416. In 19E500873G1 of REV G and earlier: In 19E500873G2 of REV H and earlier: In 19E500873G3 of REV G and earlier: N Channel; sim to T1S34. 19A115953Pl - - - - - - - CAPACITORS - - - - - - -19A116080P7 Polyester: 0.1  $\mu$ f  $\pm 20\%$ , 50 VDCW. C3 5494481P112 Ceramic disc: 1000 pf ±10%, 1000 VDCW. Silver mica: 220 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15. 5490008P35

| SYMBOL          | GE PART NO.        | DESCRIPTION  |
|-----------------|--------------------|--|
| C6              | 5490008 <b>P</b> 9 | Silver mica: 18 pf ±5%, 500 VDCW; sim to   |
| C7<br>and       | 19A116080P5        | Electro Motive Type DM-15. Polyester: 0.047 μf ±20%, 50 VDCW.  |
| C8<br>C9        | 5496219P369        | Ceramic disc: 180 pf ±5%, 500 VDCW, temp coe -150 PPM.   |
| C10             | 19A116080P7        | Polyester: 0.1 µf ±20%, 50 VDCW.   |
| C11             | 5496219P40         | Ceramic disc: 9 pf ±0.25 pf, 500 VDCW, temp coef 0 PPM.  |
| C12             | 5496219P369        | Ceramic disc: 18 pf ±5%, 500 VDCW, temp coef -150 PPM.   |
| C13             | 5496219P40         | Ceramic disc: 9 pf ±0.25 pf, 500 VDCW, temp coef 0 PPM.  |
| C14             | 19A116656P220J2    | Ceramic disc: 220 pf ±5%, 500 VDCW, temp coe-<br>-220 PPM.   |
| C15             | 7491395P109        | Ceramic disc: 1000 pf $\pm 10\%,~500$ VDCW; sim to RMC Type JL.  |
| C16             | 19A116080P5        | Polyester: 0.047 μf ±20%, 50 VDCW.   |
| C17             | 19A116080P1        | Polyester: 0.01 μf ±20%, 50 VDCW.  |
| J1              | 4033513P4          | JACKS AND RECEPTACLES Contact, electrical; sim to Bead Chain L93-3.  |
|                 | 100001011          | onner, erectrour, sim to send online soo of  |
|                 |                    | INDUCTORS  |
| Ll              | 19C311181G3        | Coil. Includes tuning slug 4038368Pl.  |
| L2<br>and<br>L3 | 19A115711P1        | Transformer, freq: 455 KHz; sim to Automatic Mfg EX12670.  |
|                 |                    |  |
| P1              | 4029840P2          | Contact, electrical: sim to Amp 42827-2.   |
| P2              | 4029840P1          | Contact, electrical: sim to AMP 41854.   |
|                 |                    |  |
| Q1              | 19A115889P1        | Silicon, NPN.  |
| Q2              | 19A115245P1        | Silicon, NPN.  |
| Q3              | 19A115123P1        | Silicon, NPN; sim to Type 2N2712.  |
|                 |                    | RESISTORS  |
| R1<br>and<br>R2 | 3R77P103K          | Composition: 10,000 ohms ±10%, 1/2 w.  |
| R3              | 3R77P512J          | Composition: 5100 ohms ±5%, 1/2 w.   |
| R4              | 3R152P333K         | Composition: 33,000 ohms ±10%, 1/4 w.  |
| R5              | 3R152P103J         | Composition: 10,000 ohms ±5%, 1/4 w.   |
| R6              | 3R77P332K          | Composition: 3300 ohms ±10%, 1/2 w.  |
| R7              | 3R77P123K          | Composition: 12,000 ohms $\pm 10\%$ , $1/2$ w.   |
| R8              | 3R77P622J          | Composition: 6200 ohms ±5%, 1/2 w.   |
| R9              | 3R77P302J          | Composition: 3000 ohms $\pm 5\%$ , $1/2$ w.  |
| R10             | 3R77P202J          | Composition: 2000 ohms ±5%, 1/2 w.   |
| R11             | 3R77P201J          | Composition: 200 ohms ±5%, 1/2 w.  |
| т1              |                    |  |
| 12              |                    | 19B216120G1  |
| C1              | 19C301540P261      | Companie discussion 52 of the Compan |
|                 | 5491798P3          | Ceramic disc: 82 pf ±5%, 200 VDCW, temp coef -80 PPM.  |
|                 | 349179623          | Tuning slug.   |
| V1              | 10411010202        | Charter than ANAE Will thou We at 05 c   |
| Y1              | 19A110192P3        | Quartz: freq $4845$ KHz $\pm 100$ Hz at $25$ °C, temp range $-30$ °C to $+75$ °C.  |
|                 |                    |  |
|                 |                    |  |
|                 |                    |  |
|                 |                    |  |
|                 |                    |  |
|                 |                    |  |
|                 |                    |  |

|      | SYMBOL            | GE PART NO.                | DESCRIPTION   |
|------|-------------------|----------------------------|---|
| to   | A348              |                            | IF AUDIO AND SQUELCH<br>19D413129G1                                   |
|      |                   |                            |   |
|      | C1                | 5494481P111                | Ceramic disc: 1000 pf ±20%, 1000 VDCW;                                |
| coef | C2                | 5496219P717                | Ceramic disc: 47 pf ±10%, 500 VDCW, tem                               |
| mp   | СЗ                | 5494481P111                | -750 PPM.  Ceramic disc: 1000 pf ±20%, 1000 VDCW;                     |
| oef  | C4                | 5496219P717                | RMC Type JF Discap.  Ceramic disc: 47 pf ±10%, 500 VDCW, ten          |
| p    | C5                | 5494481P111                | -750 PPM.  Ceramic disc: 1000 pf ±20%, 1000 VDCW;                     |
|      | and<br>C6         |                            | RMC Type JF Discap.   |
| coef | C7                | 19A116080P5                | Polyester: 0.047 µf ±20%, 50 VDCW.                                    |
| :0   | C8                | 19A116656P180J1            | Ceramic disc: 180 pf $\pm 5\%$ , 500 VDCW, tem $-150$ PPM.            |
|      | C9<br>and<br>C10  | 5490008P37                 | Silver mica: 270 pf ±5%, 500 VDCW; sim Electro Motive Type DM-15.     |
| _    | C11               | 5496219P656                | Ceramic disc: 51 pf $\pm$ 5%, 500 VDCW, temp coef $-470$ PPM.         |
| ·з,  | C12               | 5494481Pl08                | Ceramic disc: 470 pf ±10%, 1000 VDCW; RMC Type JF Discap.             |
|      | C13               | 19A115680P107              | Electrolytic: 100 µf +150% -10%, 15 VDC to Mallory Type TT.           |
|      | C14               | 19A115680Pl04              | Electrolytic: 50 µf +150% -10%, 25 VDCW                               |
| ic   | and<br>C15        |                            | to Mallory Type TT.   |
|      | C16               | 5494481P112                | Ceramic disc: 1000 pf $\pm 10\%$ , 500 VDCW; s to RMC Type JF Discap. |
|      | C17               | 19A116080P7                | Polyester: 0.1 µf ±20%, 50 VDCW.                                      |
|      | C18               | 5494481P108                | Ceramic disc: 470 pf ±10%, 1000 VDCW; s<br>RMC Type JF Discap.        |
| -    | C19<br>and<br>C20 | 19A116080P5                | Polyester: 0.047 μf ±20%, 50 VDCW.                                    |
|      | C21               | 19A116080P3                | Polyester: 0.022 $\mu f$ ±20%, 50 VDCW.                               |
|      | C22               | 19A116080P108              | Polyester: 0.15 μf ±10%, 50 VDCW. Polyester: 0.1 μf ±10%, 50 VDCW.    |
|      | C23<br>C25        | 19A116080P107<br>5496267P6 | Tantalum: 33 μf ±20%, 10 VDCW; sim to                                 |
|      | C26*              |                            | Sprague Type 150D.  Polyester: 0.33 µf ±10%, 50 VDCW.                 |
|      | C26*              | 19A116080P110              | In REV E-M:   |
|      |                   | 19A116080P109              | Polyester: 0.22 $\mu f$ ±10%, 50 VDCW.                                |
|      |                   | E406967D00                 | In REV D and earlier:   |
|      |                   | 5496267P28                 | Tantalum: 0.47 µf ±20%, 35 VDCW; sim to Sprague Type 150D.            |
|      | C27               | 5496267P2                  | Tantalum: 47 $\mu$ f $\pm 20\%$ , 6 VDCW; sim to Sprague Type 150D.   |
|      | C30               | 19A116080P8                | Polyester: 0.15 µf ±20%, 50 VDCW.                                     |
|      | C31               | 19A116080P102              | Polyester: 0.015 µf ±20%, 50 VDCW.                                    |
|      | C32<br>C33        | 19A116080P7                | Polyester: 0.1 µf ±20%, 50 VDCW. Polyester: 0.22 µf ±20%, 50 VDCW.    |
|      | C34               | 4029003P207                | Silver mica: 1830 pf ±2%, 500 VDCW; sim<br>Electro Motive Type DM-20. |
|      | C35               | 19A116080P5                | Polyester: 0.047 µf ±20%, 50 VDCW.                                    |
|      | C36               | 19A116080P9                | Polyester: 0.22 $\mu f$ ±20%, 50 VDCW.                                |
| pef  | C37               | 5496267P28                 | Tantalum: 0.47 $\mu f$ ±20%, 35 VDCW; sim to Sprague Type 150D.       |
|      | C39               | 19A116080P1                | Polyester: 0.01 µf ±20%, 50 VDCW.                                     |
|      | C40*              | 5496267 <b>P2</b> 9        | Tantalum: 0.68 µf ±20%, 35 VDCW; sim to Sprague Type 150D.            |
|      |                   | 5496267P28                 | In REV K and earlier: Tantalum: 0.47 µf ±20%, 35 VDCW; sim to         |
|      |                   |                            | Sprague Type 150D.  |
|      | C41               | 5490008P129                | Silver mica: 120 pf ±10%, 500 VDCW; sim<br>Electro Motive Type DM-15. |
|      | C50               | 19A116080P7                | Polyester: 0.1 µf ±20%, 50 VDCW.                                      |
|      |                   |                            |   |
|      |                   |                            |   |

| DESCRIPTION  | SYMBOL            | GE PART NO.            | DESCRIPTION  |
|--|-------------------|------------------------|--|
| IF AUDIO AND SQUELCH<br>19D413129G1                                      | C51               | 19All6655P22           | Ceramic disc: 2700 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.                            |
|  | C52               | 19A116080P109          | Polyester: 0.22 µf ±10%, 50 VDCW.  |
| Ceramic disc: 1000 pf $\pm 20\%,$ 1000 VDCW; sim to RMC Type JF Discap.  | C53<br>and<br>C54 | 5496267P213            | Tantalum: 2.2 $\mu f$ $\pm 10\%$ , 20 VDCW; sim to Sprague Type 150D.                        |
| Ceramic disc: 47 pf $\pm 10\%$ , 500 VDCW, temp coef -750 PPM.           | C55               | 5496267P14             | Tantalum: 15 µf ±20%, 20 VDCW; sim to Sprague Type 150D.                                     |
| Ceramic disc: 1000 pf $\pm 20\%$ , 1000 VDCW; sim to RMC Type JF Discap. |                   |                        | DIODES AND RECTIFIERS  |
| Ceramic disc: 47 pf $\pm 10\%$ , 500 VDCW, temp coef $-750$ PPM.         | CR1<br>and<br>CR2 | 19A115250P1            | Silicon.   |
| Ceramic disc: 1000 pf $\pm 20\%$ , 1000 VDCW; sim to RMC Type JF Discap. | CR3*<br>and       | 19A115250P1            | Silicon.   |
| Polyester: 0.047 $\mu$ f $\pm 20\%$ , 50 VDCW.                           | CR4*              |                        | In REV F and earlier:  |
| Ceramic disc: 180 pf ±5%, 500 VDCW, temp coef -150 PPM.                  |                   | 4038056P1              | Germanium.   |
| Silver mica: 270 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.     | CR5<br>and<br>CR6 | 19A115250P1            | Silicon.   |
| Ceramic disc: 51 pf ±5%, 500 VDCW,                                       |                   |                        | JACKS AND RECEPTACLES  |
| temp coef -470 PPM.  | J1<br>thru        | 4033513P4              | Contact, electrical: sim to Bead Chain L93-3.  |
| Ceramic disc: 470 pf $\pm 10\%$ , 1000 VDCW; sim to RMC Type JF Discap.  | J18               | 400051004              | Contract plantated and the Book Chair 102 2  |
| Electrolytic: 100 $\mu f$ +150% -10%, 15 VDCW; sim to Mallory Type TT.   | J18A<br>J19       | 4033513P4<br>4033513P4 | Contact, electrical: sim to Bead Chain L93-3.  Contact, electrical: sim to Bead Chain L93-3. |
| Electrolytic: 50 μf +150% -10%, 25 VDCW; sim                             | thru<br>J22       | 100001014              |  |
| to Mallory Type TT.  |                   |                        | INDUCTORS  |
| Ceramic disc: 1000 pf $\pm 10\%$ , 500 VDCW; sim to RMC Type JF Discap.  | Ll                | 19A115711P6            | Transformer, freq: 455 KHz; sim to TOKO PEFCN-14833-CX12.                                    |
| Polyester: 0.1 µf ±20%, 50 VDCW.   | L2                | 19A115711P7            | Transformer, freq: 455 KHz; sim to TOKO PEFCN-14834-BNL2.                                    |
| Ceramic disc: 470 pf $\pm 10\%$ , 1000 VDCW; sim to RMC Type JF Discap.  | r3                | 19A127134G1            | Choke. Includes tuning slug 7486872P7.   |
| Polyester: 0.047 µf ±20%, 50 VDCW.                                       |                   |                        | TRANSISTORS  |
| Polyester: 0.022 µf ±20%, 50 VDCW.                                       | Q1<br>thru<br>Q4  | 19A115123P1            | Silicon, NPN; sim to Type 2N2712.  |
| Polyester: 0.15 µf ±10%, 50 VDCW.  | Q5                | 19A115889P1            | Silicon, NPN; sim to Type 2N2712.  |
| Polyester: 0.1 µf ±10%, 50 VDCW.   | Q6                | 19A115123P1            | Silicon, NPN; sim to Type 2N2712.  |
| Tantalum: 33 $\mu$ f $\pm$ 20%, 10 VDCW; sim to Sprague Type 150D.       | Q7                | 19A115300P4            | Silicon, NPN; sim to Type 2N3053.  |
| Polyester: 0.33 $\mu$ f $\pm$ 10%, 50 VDCW.                              | Q8                | 19A115123P1            | Silicon, NPN; sim to Type 2N2712.  |
| In REV E-M:  | Q9                | 19A115362P1            | Silicon, NPN; sim to Type 2N2925.  |
| Polyester: 0.22 µf ±10%, 50 VDCW.  | Q10*              | 19A116774P1            | Silicon, NPN; sim to Type 2N5210.  |
| In REV D and earlier:  Tantalum: 0.47 µf ±20%, 35 VDCW; sim to           |                   | 19A115123P1            | In REV G and earlier: Silicon, NPN; sim to Type 2N2712.                                      |
| Sprague Type 150D.   |                   | 19811312321            | Silicon, NPN, Sim to Type 2M2/12.  |
| Tantalum: $47~\mu f~\pm 20\%$ , $6~VDCW$ ; sim to Sprague Type 150D.     |                   |                        | RESISTORS  |
| Polyester: 0.15 µf ±20%, 50 VDCW.  | R1                | 3R77P102K              | Composition: 1000 ohms ±10%, 1/2 w.  |
| Polyester: 0.015 $\mu f$ ±20%, 50 VDCW.                                  | R2<br>R3          | 3R77P153J<br>3R77P823K | Composition: 15,000 ohms ±5%, 1/2 w.  Composition: 82,000 ohms ±10%, 1/2 w.                  |
| Polyester: 0.1 µf ±20%, 50 VDCW.   | R4                | 3R77P472K              | Composition: 4700 ohms ±10%, 1/2 w.  |
| Polyester: 0.22 µf ±20%, 50 VDCW.  | R5                | 3R77P102K              | Composition: 1000 ohms ±10%, 1/2 w.  |
| Silver mica: 1830 pf ±2%, 500 VDCW; sim to Electro Motive Type DM-20.    | R6                | 3R77P153J              | Composition: 15,000 ohms ±5%, 1/2 w.   |
| Polyester: 0.047 $\mu$ f ±20%, 50 VDCW.                                  | R7                | 3R77P823K              | Composition: 82,000 ohms ±10%, 1/2 w.  |
| Polyester: 0.22 µf ±20%, 50 VDCW.  | R8                | 3R77P472K              | Composition: 4700 ohms ±10%, 1/2 w.  |
| Tantalum: 0.47 µf ±20%, 35 VDCW; sim to Sprague Type 150D.               | R9                | 3R77P102K              | Composition: 1000 ohms ±10%, 1/2 w.  |
| Polyester: 0.01 µf ±20%, 50 VDCW.  | R10               | 3R77P153J              | Composition: 15,000 ohms ±5%, 1/2 w.   |
| Tantalum: 0.68 µf ±20%, 35 VDCW; sim to                                  | R11               | 3R77P823K              | Composition: 82,000 ohms ±10%, 1/2 w.  |
| Sprague Type 150D. In REV K and earlier:                                 | R12<br>R13        | 3R77P472K<br>3R77P272K | Composition: 4700 ohms ±10%, 1/2 w.  Composition: 2700 ohms ±10%, 1/2 w.                     |
| Tantalum: 0.47 µf ±20%, 35 VDCW; sim to                                  | R13               | 3R77P272K<br>3R77P103J | Composition: 10,000 ohms ±5%, 1/2 w.   |
| Sprague Type 150b. Silver mica: 120 pf ±10%, 500 VDCW; sim to            |                   | 3                      |  |
| Electro Motive Type DM-15.   |                   |                        |  |
| Polyester: 0.1 µf ±20%, 50 VDCW.   |                   |                        |  |

| SYMBOL            | . GE PART NO.          | DESCRIPTION   |              | SYMBOL     | GE PART NO.                  |
|-------------------|------------------------|---|--------------|------------|------------------------------|
| R15               | 3R77P333J              | Composition: 33,000 ohms ±5%, 1//2 w.   | 71           | -555       | 0-150-150-                   |
| R16               | 3R77P181K              |   | 11           | R77        | 3R152P153K                   |
| R17               | 3R152P471J             |   |              | R78*       | 3R77P200J                    |
| R17               | 3R152P4713             |   |              |            |                              |
| and<br>R19        | 3R152P5133             | Composition: 51,000 ohms ±5%, 1/4 w.  | Ш            | R79        | 3R77P100J<br>3R152P393J      |
| R20               | 3R152P472K             | Composition: 4700 ohms ±10%, 1/4 w.   | Ш            | R80*       | 3R152P272J                   |
| R21<br>and<br>R22 | 3R77P362J              | Composition: 3600 ohms $\pm 5\%$ , $1/2$ w.                                       | Ш            |            | 3R152P432J                   |
| R23               | 3R77P104K              | Composition: 0.1 megohm ±10%, 1/2 w.  | $ \cdot $    | R81        | 3R152P472J                   |
| R24               | 3R152P102J             | Composition: 1000 ohms ±5%, 1/4 w.  | 11           | R82        | 3R77P273J                    |
| R25<br>and<br>R26 | 3R77P103K              | Composition: 10,000 ohms ±10%, 1/2 w.   |              | R85*       | 3R152P102J                   |
| R27<br>and        | 3R77P753J              | Composition: 75,000 ohms ±5%, 1/2 w.  | Ш            |            |                              |
| R28<br>R29        | 3R77P182J              | Composition, 1900 chara teg. 1/0  | $ \cdot $    | RT1        | 5490828P41                   |
| R29               | 3R77P182J<br>3R77P821J | Composition: 1800 ohms ±5%, 1/2 w.  | ш            | RT2        | 5490828P9                    |
| K30*              | 3R77P82IJ              | Composition: 820 ohms ±5%, 1/2 w.  In REV C and earlier:                          | 11           | and<br>RT3 |                              |
|                   | 3R77P102J              |   | Ш            |            |                              |
| R31               | 3R77P821J              | Composition: 1000 ohms ±5%, 1/2 w.  Composition: 820 ohms ±5%, 1/2 w.             | Ш            | т1         | 19Al16040Pl                  |
| R33               | 3R77P912J              | Composition: 9100 ohms ±5%, 1/2 w.  |              |            |                              |
| R34               | 3R77P332K              | Composition: 3300 ohms ±10%, 1/2; w.  | Ш            |            |                              |
| R35               | 3R77P332K              | Composition: 33 ohms ±10%, 1/2 w.   |              | A350       |                              |
| R36               | 3R77P681J              | Composition: 680 ohms ±5%, 1/2 w.   |              |            |                              |
| R38               | 3R77P752J              | Composition: 7500 ohms ±5%, 1/2 w.  |              | a2         | 10411600070                  |
| R39               | 3R77P820J              | Composition: 82 ohms ±5%, 1/2 w.  | ш            | C1<br>C2   | 19A116080P9<br>19A116080P205 |
| R40*              | 3R77P221J              | Composition: 220 ohms ±5%, 1/2 w.   | Ш            | and        | 194116080P205                |
|                   |                        | In REV H and earlier:   | 11           | C3<br>C4   | 19A116080P207                |
|                   | 3R77P241J              | Composition: 240 ohms ±5%, 1/2 w.   | 11           | C5         | 19A116080P7                  |
| R41               | 3R152P240J             | Composition: 24 ohms ±5%, 1/4 w.  | $\mathbf{I}$ | C6         | 19A116080P205                |
| R42               | 3R77P200J              | Composition: 20 ohms ±5%, 1/2 w.  | Ш            | C7         | 19A116080P207                |
| R43               | 19B209358P101          | Variable, carbon film: approx 25 to 250 ohms ±10%, 0.2 w; sim to CTS Type X-20:1. | 11           | C8         | 19A116080P205                |
| R44               | 19B209022P101          | Wirewound: 0.27 ohms ±10%, 2 w; sim to IRC  |              | C9         | 19A116080P9                  |
| 245               | 207701021              | Type BWH.  Composition: 12,000 ohms ±5%, 1/2 w.                                   |              | C10        | 19A116080P207                |
| R45               | 3R77P123J<br>3R77P913J | Composition: 12,000 ohms ±5%, 1/2 w.  Composition: 91,000 ohms ±5%, 1/2 w.        | Ш            | C11        | 19Al16080P109                |
| R46<br>R48        | 19A116278P249          | Metal film: 3160 ohms ±2%, 1/2 w.   |              | C12        | 19A116080P207                |
| R49               | 3R77P103J              | Composition: 10,000 ohms ±5%, 1/2 w.  | Ш            | C13        | 19A116080P9                  |
| R49               | 3R77P222J              | Composition: 2200 ohms ±5%, 1/2 w.  | 11           | C14        | 19A116080P7                  |
| R51               | 3R77P103J              | Composition: 10,000 ohms ±5%, 1/2 w.  | Ш            | C15        | 5496267P1                    |
| R51               | 3R77P1033              | Composition: 6800 ohms ±5%, 1/2 w.  |              | C16        | 19A116080P5                  |
| R52               | 3R77P223J              | Composition: 22,000 ohms ±5%, 1/2 w.  |              | C17        | 5496267P417                  |
|                   |                        | In REV E and earlier:   |              | C18        | 5496267P1                    |
|                   | 3R77P303J              | Composition: 30,000 ohms ±5%, 1/2 w.  |              |            |                              |
| R54               | 3R77P822J              | Composition: 8200 ohms $\pm 5\%$ , $1/2$ w.                                       |              | C19        | 19A116080P109                |
| R55               | 3R77P103K              | Composition: 10,000 ohms $\pm 10\%$ , $1./2$ w.                                   |              | C20        | 5494481P111                  |
|                   |                        |   |              |            |                              |

Composition: 0.22 megohm ±5%, 1/2 w.

Composition: 39,000 ohms  $\pm 10\%$ , 1./2 w.

Composition: 10,000 ohms  $\pm 10\%$ , 11/2 w.

Composition: 12 ohms ±5%, 1/2 w.

Composition: 4700 ohms  $\pm 10\%$ , 1/2 w.

3R77P181K

3R77P393K

3R77P103K

3R77P120J

3R77P472K

|                         |  | ı |                    |   |   |
|-------------------------|--|---|--------------------|---|---|
| 3R152P153K<br>3R77P200J | Composition: 15,000 ohms $\pm 10\%$ , $1/4$ w. Composition: 20 ohms $\pm 5\%$ , $1/2$ w.                                       |   | C27<br>and<br>C28  | 19A116080P210   | Polyester: 0.33 $\mu f$ ±10%, 50 VDCW.  |
|                         | In REV C and earlier:  | l | C29*               | 19A116080P205   | Polyester: 0.047 µf ±5%, 50 VDCW.   |
| 3R77P100J               | Composition: 10 ohms ±5%, 1/2 w.   | l |                    |   | In REV B and earlier:   |
| 3R152P393J              | Composition: 39,000 ohms ±5%, 1/4 w.   | l |                    | 19B209243P107   | Polyester: 0.1 µf ±10%, 50 VDCW.  |
| 3R152P272J              | Composition: 2700 ohms $\pm 5\%$ , $1/4$ w.  | l | C30                | 5496267P17  | Tantalum: 1.0 μf ±20%, 35 VDCW; sim to  |
|                         | In REV L and earlier:  | l |                    |   | Sprague Type 150D.  |
| 3R152P432J              | Composition: 4300 ohms $\pm 5\%$ , $1/4$ w.  | 1 |                    |   | DIODES AND RECTIFIERS   |
| 3R152P472J              | Composition: 4700 ohms $\pm 5\%$ , $1/4$ w.  | ı | CR1                | 19A115250P1   | Silicon.  |
| 3R77P273J               | Composition: 27,000 ohms ±5%, 1/2 w.   | L | and<br>CR2         |   |   |
| 3R152P102J              | Composition: 1000 ohms $\pm 5\%$ , $1/4$ w. Added by REV K. Deleted by REV L.  |   | CR3<br>and<br>CR4  | 5494922P1   | Silicon.  |
|                         |  | ľ | CR5                | 19A115250P1   | Silicon.  |
| 5490828P41              | Thermistor: 30 ohms ±10%, color code   | l | CR6                | 4036887P3   | Silicon, Zener.   |
| 5490828P9               | black/white; sim to Globar Type Bl211H-4.<br>Thermistor: 10,000 ohms $\pm 10\%$ , color code yellow; sim to Globar Type 551H8. |   | CR7<br>thru<br>CR9 | 19A115250P1   | Silicon.  |
|                         |  |   |                    |   | FILTERS   |
| 19A116040P1             | Audio freq: 300-4000 Hz, Pri: 19.3 ohms ±10% DC res, Sec: 23.5 ohms ±10% DC res.  ENCODER/DECODER 4EK16A10 19C311797G1         |   | FL1                | 19B205280G1<br>19B205280G2<br>19B205280G3<br>19B205280G4<br>19B205280G5<br>19B205280G6<br>19B205280G7 | TONE FREQUENCY NETWORK 19B205280  71.9 Hz 77.0 Hz 82.5 Hz 88.5 Hz 94.8 Hz 100.0 Hz 103.5 Hz |
|                         |  |   |                    | 19B205280G8<br>19B205280G9  | 107.2 Hz<br>110.9 Hz  |
| 19A116080P9             | Polyester: 0.22 $\mu f$ ±20%, 50 VDCW.   | ı |                    | 19B205280G10<br>19B205280G11  | 114.8 Hz<br>118.8 Hz  |
| 19A116080P205           | Polyester: 0.047 μf ±5%, 50 VDCW.  |   |                    | 19B205280G12<br>19B205280G13<br>19B205280G14<br>19B205280G15  | 123.0 Hz<br>127.3 Hz<br>131.8 Hz<br>136.5 Hz  |
| 19A116080P207           | Polyester: 0.1 µf ±5%, 50 VDCW.  |   |                    | 19B205280G16<br>19B205280G17  | 141.3 H2<br>146.2 Hz  |
| 19A116080P7             | Polyester: 0.1 µf ±20%, 50 VDCW.   |   |                    | 19B205280G17<br>19B205280G18<br>19B205280G19  | 151.4 Hz<br>156.7 Hz  |
| 19A116080P205           | Polyester: 0.047 µf ±5%, 50 VDCW.  | П |                    | 19B205280G20  | 162.2 Hz  |

SYMBOL GE PART NO.

DESCRIPTION

SYMBOL GE PART NO.

3R77P201J

19A116278P305

DESCRIPTION

Metal film: 11,000 ohms  $\pm 2\%$ , 1/2 w.

DESCRIPTION

Polyester: 0.1 µf ±5%, 50 VDCW.

Polyester: 0.047 µf ±5%, 50 VDCW.

Polyester: 0.22  $\mu f$  ±20%, 50 VDCW.

Polyester: 0.22  $\mu f$  ±10%, 50 VDCW.

Polyester: 0.22 μf ±20%, 50 VDCW.

Tantalum: 6.8  $\mu$ f  $\pm 20\%$ , 6 VDCW; sim to Sprague Type 150D.

Tantalum: 1.0  $\mu f$   $\pm 5\%$ , 35 VDCW; sim to Sprague Type 150D.

Tantalum: 6.8  $\mu$ f  $\pm 20\%$ , 6 VDCW; sim to Sprague Type 150D.

Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.

Tantalum: 3.3  $\mu f$   $\pm 20\%$ , 15 VDCW; sim to Sprague Type 150D.

Tantalum: 1.0  $\mu f$   $\pm 20\%$ , 35 VDCW; sim to Sprague Type 150D.

Tantalum: 2.2  $\mu f$  ±20%, 20 VDCW; sim to Sprague Type 150D.

Tantalum: 6.8  $\mu f$  ±20%, 6 VDCW; sim to Sprague Type 150D.

Tantalum:  $6.8~\mu f~\pm 20\%$ , 35~VDCW; sim to Sprague Type 150D.

Polyester: 0.068 µf ±5%, 50 VDCW.

Polyester: 0.047 µf ±10%, 50 VDCW.

Polyester: 0.047  $\mu f$  ±20%, 50 VDCW.

Polyester: 0.1 µf ±20%, 50 VDCW.

Polyester: 0.1 µf ±5%, 50 VDCW.

Polyester: 0.1  $\mu$ f  $\pm 5\%$ , 50 VDCW.

19A116080P206

C21 5496267P9

C22 5496267P17

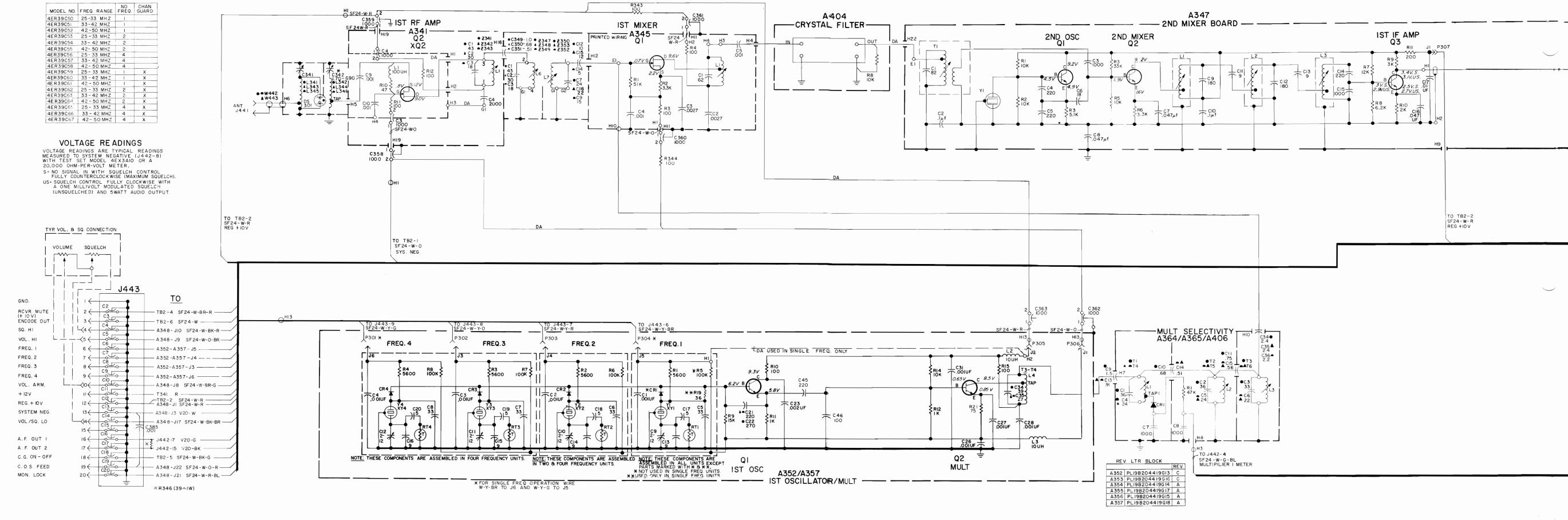
C23 5496267P13

C24 5496267P1

C25 5496267P18

C26

|   | C29*        | 19A116080P205                | Polyester: 0.047 µf ±5%, 50 VDCW.            | ı | R8*        | 3R77P562J     | Composition: 5600 ohms $\pm 5\%$ , $1/2$ w.                               |
|---|-------------|------------------------------|--|---|------------|---------------|---|
|   |             |                              | In REV B and earlier:                        | l |            |               | Earlier than REV A:   |
|   |             | 19B209243P107                | Polyester: 0.1 µf ±10%, 50 VDCW.             | 1 |            | 3R152P622J    | Composition: 6200 ohms $\pm 5\%$ , $1/4$ w.                               |
|   | C30         | 5496267P17                   | Tantalum: 1.0 µf ±20%, 35 VDCW; sim to       | l | R9         | 19A116278P305 | Metal film: 11,000 ohms ±2%, 1/2 v  |
|   |             |                              | Sprague Type 150D.                           | l | R10        | 3R77P512J     | Composition: 5100 ohms ±5%, 1/2 w.  |
|   |             |                              | DIODES AND RECTIFIERS                        | ı | R11        | 3R77P103J     | Composition: 10,000 ohms ±5%, 1/2   |
|   | CR1         | 19A115250P1                  | Silicon.                                     | ı | R12        | 3R77P822J     | Composition: 8200 ohms ±5%, 1/2 w.  |
|   | and<br>CR2  |                              |  | l | R13        | 3R77P153J     | Composition: 15,000 ohms ±5%, 1/2   |
|   | CR3         | 5494922P1                    | Silicon.                                     | ı | Rl4        | 3R77P133J     | Composition: 13,000 ohms ±5%, 1/2   |
|   | and<br>CR4  |                              |  | ı | R15        | 3R77P510J     | Composition: 51 ohms ±5%, 1/2 w.  |
|   | CR5         | 19A115250P1                  | Silicon.                                     | l | R16        | 3R77P153J     | Composition: 15,000 ohms ±5%, 1/2   |
|   | CR6         | 4036887P3                    | Silicon, Zener.                              | ١ | R17        | 3R77P103J     | Composition: 10,000 ohms ±5%, 1/2   |
|   | CR7         | 19A115250P1                  | Silicon.                                     | l | R18        | 3R77P622J     | Composition: 6200 ohms ±5%, 1/2 w.  |
|   | thru<br>CR9 |                              |  | ı | R19        | 3R77P123J     | Composition: 12,000 ohms ±5%, 1/2   |
|   | ·           |                              |  | l | R20        | 3R77P223J     | Composition: 22,000 ohms ±5%, 1/2   |
|   | FL1         |                              | TONE FREQUENCY NETWORK                       | ı | R21        | 3R77P103J     | Composition: 10,000 ohms ±5%, 1/2   |
|   |             |                              | 19B205280                                    | l | R22        | 3R77P301J     | Composition: 300 ohms ±5%, 1/2 w.   |
|   |             | 19B205280G1<br>19B205280G2   | 71.9 Hz<br>77.0 Hz                           | ı | R23        | 3R77P223J     | Composition: 22,000 ohms ±5%, 1/2   |
| - |             | 19B205280G3<br>19B205280G4   | 82.5 Hz<br>88.5 Hz                           | l | R24        | 3R77P433J     | Composition: 43,000 ohms ±5%, 1/2   |
| - |             | 19B205280G5<br>19B205280G6   | 94.8 Hz<br>100.0 Hz                          | ı | l          |               | Composition: 13,000 ohms ±5%, 1/2   |
| ١ |             | 19B205280G7                  | 103.5 Hz                                     | l | R25        | 3R77P133J     |   |
| 1 |             | 19B205280G8<br>19B205280G9   | 107.2 Hz<br>110.9 Hz                         | l | R26        | 3R77P123J     |   |
| 1 |             | 19B205280G10<br>19B205280G11 | 114.8 Hz<br>118.8 Hz                         | l | R27        | 3R77P151J     |   |
| 1 |             | 19B205280G12<br>19B205280G13 | 123.0 Hz<br>127.3 Hz                         | l | R28        | 3R77P562J     | Composition: 5600 ohms ±5%, 1/2 w.  |
| ١ |             | 19B205280G14<br>19B205280G15 | 131.8 Hz<br>136.5 Hz                         | l | R29        | 3R77P513J     | Composition: 51,000 ohms ±5%, 1/2   |
|   |             | 19B205280G16<br>19B205280G17 | 141.3 Hz<br>146.2 Hz                         | l | R30        | 3R77P334J     | Composition: 0.33 megohm ±5%, 1/2   |
|   |             | 19B205280G18<br>19B205280G19 | 151.4 Hz<br>156.7 Hz                         | l | R31        | 3R77P104J     | Composition: 0.1 megohm ±5%, 1/2 w  |
| - |             | 19B205280G20<br>19B205280G21 | 162.2 Hz<br>167.9 Hz                         | ı | R32        | 3R77P822J     | Composition: 8200 ohms ±5%, 1/2 w.  |
| - |             | 19B205280G22<br>19B205280G23 | 173.8 Hz<br>179.9 Hz                         | ١ | R33        | 19A116278P342 | Metal film: 26,700 ohms ±2%, 1/2 v  |
| 1 |             | 19B205280G24<br>19B205280G25 | 186.2 Hz<br>192.8 Hz                         | l | R34        | 19A116278P233 | Metal film: 2150 ohms ±2%, 1/2 w.   |
| ١ |             | 19B205280G26                 | 203.5 Hz                                     | ì | R35        | 19A116278P365 | Metal film: 46,400 ohms ±2%, 1/2 v  |
|   |             |                              | JACKS AND RECEPTACLES                        | ı | R36        | 19A116278P301 | Metal film: 10,000 ohms ±2%, 1/2 v  |
| ١ | J1          | 4033513P4                    | Contact, electrical sim to Bead Chain L93-3. | l | R37        | 19A116278P65  | Metal film: 46.4 ohms ±2%, 1/2 w.   |
| - | thru<br>J8  |                              |  | ı | R38        | 3R77P204J     | Composition: 0.20 megohm ±5%, 1/2   |
| - |             |                              |  | l | R39        | 19A116278P385 | Metal film: 75,000 ohms ±2%, 1/2 v  |
| ١ | Ll          | 19A115690P1                  | Coil, RF: 880 mh ±5%, sim to Artted AC5672.  | ı | R40        | 19A116278P329 | Metal film: 19,000 ohms ±2%, 1/2 v  |
| ١ | 21          |                              | ,  | l | R41        | 19A116278P285 | Metal film: 7500 ohms ±2%, 1/2 w.   |
| ١ |             |                              |  | ı | R42        | 19A116278P412 | Metal film: 130,000 ohms ±2%, 1/2   |
| ١ | Q1          | 19A115123P1                  | Silicon, NPN; sim to Type 2N2712.            | ı | R43        | 19A116278P269 | Metal film: 5110 ohms ±2%, 1/2 w.   |
| ١ | Q2          | 19A115362P1                  | Silicon, NPN; sim to Type 2N2925.            | ı | R44        | 19A116278P117 | Metal film: 147 ohms $\pm 2\%$ , $1/2$ w.                                 |
| - | Q3          | 19A115123Pl                  | Silicon, NPN; sim to Type 2N2712.            | l | R45        | 3R77P102J     | Composition: 1000 ohms ±5%, 1/2 w.  |
| - | and<br>Q4   |                              |  | l | and<br>R46 |               |   |
| 1 | Q5          | 19A115362Pl                  | Silicon, NPN; sim to Type 2N2925.            | l |            |               | <u>NOTE</u><br>The value of Resistor R47 must be o                        |
| ١ | thru<br>Q8  |                              |  | l |            |               | the component, then find correspond<br>in parts list for the correct part |
| ١ | Q9          | 19A115123P1                  | Silicon, NPN; sim to Type 2N2712.            | ١ |            | 0             | _   |
| ١ | and<br>Q10  |                              |  | l | R47A       | 3R77P822J     | Composition: 8200 ohms ±5%, 1/2 w   |
| ١ |             |                              | RESISTORS                                    | l | R47B       | 3R77P912J     | Composition: 9100 ohms ±5%, 1/2 w   |
|   | R1          | 3R77P682K                    | Composition: 6800 ohms $\pm 10\%$ , $1/2$ w. |   | R47C       | 3R77P103J     | Composition: 10,000 ohms ±5%, 1/2   |
|   | R2          | 3R77P683J                    | Composition: 68,000 ohms ±5%, 1/2 w.         |   | R47D       | 3R77P113J     | Composition: 11,000 chms ±5%, 1/2   |
| ١ | R3          | 3R77P822J                    | Composition: 8200 ohms ±5%, 1/2 w.           |   | R47E       | 3R77P123J     | Composition: 12,000 ohms ±5%, 1/2   |
|   | R4          | 3R77P152J                    | Composition: 1500 ohms ±5%, 1/2 w.           |   | R47F       | 3R77P133J     | Composition: 13,000 ohms ±5%, 1/2   |
|   | R5          | 3R77P682K                    | Composition: 6800 ohms $\pm 10\%$ , $1/2$ w. | 1 | R47G       | 3R77P153J     | Composition: 15,000 ohms ±5%, 1/2   |
|   |             |                              |  |   | R47H       | 3R77P752J     | Composition: 7500 ohms ±5%, 1/2 w   |
| ١ |             |                              |  |   |            |               |   |
|   |             |                              |  |   |            |               |   |
| ١ |             |                              |  |   |            |               |   |



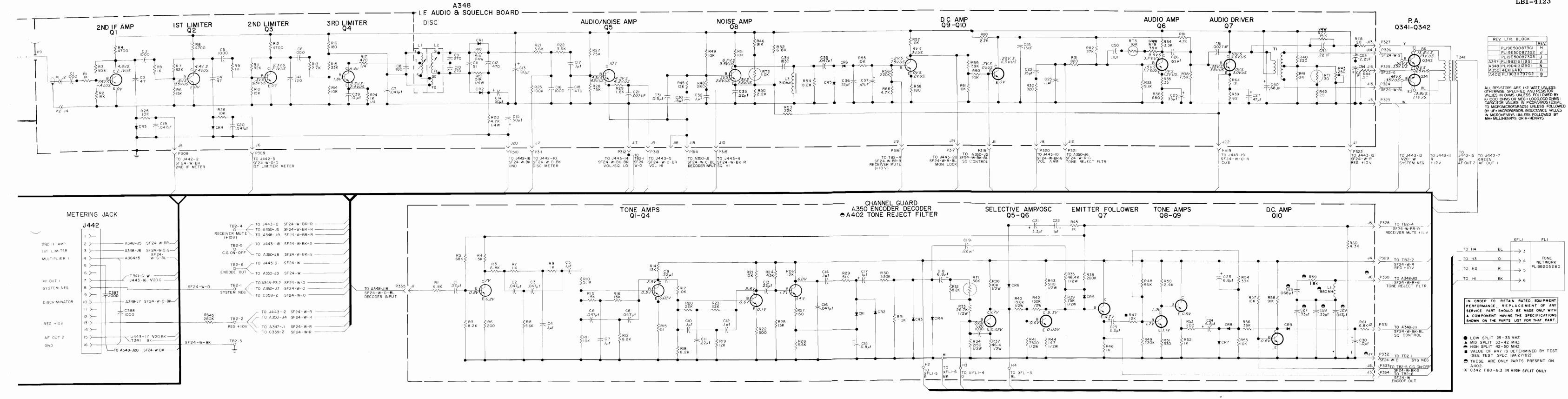
# SCHEMATIC DIAGRAM

Issue 8

25—50 MHz RECEIVER MODELS 4ER39C50-67

(19D402991, Rev. 0)

(19R621227, Rev. 34)



(19R621227, Rev. 34)

# SCHEMATIC DIAGRAM

25—50 MHz RECEIVER MODELS 4ER39C50-67

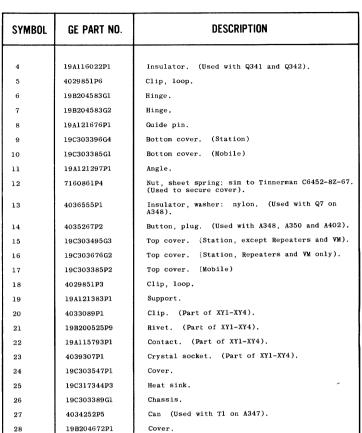
Issue 8

(Cont'd from Page 11) (LBI-4127)

| (Cont'       | (Cont'd from Page 11) (LBI-4127) |  |                  |               |   |                 |                      |   |                      |                               |   |              |               |   |               |                          |  |              |
|--------------|----------------------------------|--|------------------|---------------|---|-----------------|----------------------|---|----------------------|-------------------------------|---|--------------|---------------|---|---------------|--------------------------|--|--------------|
| SYMBOL       | GE PART NO.                      | DESCRIPTION  | SYMBOL           | GE PART NO.   | DESCRIPTION   | SYMBOL          | GE PART NO.          | DESCRIPTION   | SYMBOL               | GE PART NO.                   | DESCRIPTION   | SYMBOL       | GE PART NO.   | DESCRIPTION   | SYMBOL        | GE PART NO.              | DESCRIPTION  | SYMBOL       |
| R48          | 3R77P563J                        | Composition: 56,000 ohms ±5%, 1/2 w.   |                  |               | JACKS AND RECEPTACLES   | A364,           |                      | MULTIPLIER SELECTIVITY ASSEMBLY                       |                      |                               | INDUCTORS   | P319         | 4029840P2     | Contact, electrical; sim to Amp 42827-2.  | сз            | 54962:18P245             | Ceramic disc: 18 pf ±5%, 500 VDCW, temp coef   | 4            |
| R49          | 3R77P224J                        | Composition: 0.22 megohm ±5%, 1/2 w.   | J1               | 4033513P4     | Contact, electrical: sim to Bead Chain L93-3.   | A365<br>and     |                      | A364 19B205326G6<br>A365 19B205326G7                  | Ll                   | 19A115690Pl                   | Coil, RF: 880 mh $\pm 5\%$ , sim to Artted AC5672.  | P320         |               |   |               |                          | -80 PPM,   | 5            |
| R50          | 3R77P242J                        | Composition: 2400 ohms ±5%, 1/2 w.   | thru<br>J6       |               |   | A406            |                      | A406 19B205326G8                                      |                      |                               | RESISTORS   | P322         | 4029840P2     | Contact, electrical; sim to Amp 42827-2.  |               |                          | MISCELLANEOUS  | 6            |
| R51          | 3R77P331J                        | Composition: 330 ohms ±5%, 1/2 w.  |                  |               |   |                 |                      | CAPACITORS  | R59*                 | 3R77P182J                     | Composition: 1800 ohms ±5%, 1/2 w.  | P323         | 4029840P1     | Contact, electrical; sim to Amp 41854.  |               | 54917798P1               | Tuning slug. (Used in Z347).   | 7            |
| R52          | 3R77P102J                        | Composition: 1000 ohms ±5%, 1/2 w.   | L2               | 7488079P16    | Choke, RF: 10 µh ±10% ind at 640 ma, 0.6 ohm  | C1              | 5496218P252          | Ceramic disc: 36 μf ±5%, 500 VDCW, temp coef          |                      |                               | In REV A and earlier:   | P324         | 4029840P2     | Contact, electrical; sim to Amp 42827-2.  |               | 54917/98 <b>P</b> 4      | Tuning slug. (Used in Z348).   | 8            |
| R53          | 3R77P201J                        | Composition: 200 ohms: ±5%, 1/2 w.   | and<br>L3        |               | DC res; sim to Jeffers 4421-7K.   | and<br>C2       |                      | -80 PPM.  |                      | 3R152P432J                    | Composition: 4300 ohms ±5%, 1/4 w.  | P325<br>and  | 4029840P2     | Contact, electrical; sim to Amp 42827-2.  |               | 54917/98 <b>p</b> 5      | Tuning slug. (Used in Z349).   | 9            |
| R54          | 3R77P333J                        | Composition: 33,000 ohms ±5%, 1/2 w.   |                  |               | TRANSISTORS   | С3              | 5496218P251          | Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef -80 PPM. | A404                 |                               | CRYSTAL FILTER  | P326         |               |   | Z350,         |                          | COIL ASSEMBLY  | 10           |
| R55          | 3R77P103J                        | Composition: 10,000 ohms ±5%, 1/2 w.   | Q1<br>and        | 19All5330Pl   | Silicon, NPN.   | C4              | 5496218P248          | Ceramic disc: 24 pf ±5%, 500 VDCW, temp coef          | 1404                 |                               | 19B204616G10  | P327         | 4029840P1     | Contact, electrical; sim to Amp 41854.  | Z351*<br>Z352 |                          | Z350 19B204784G8<br>Z351* 19B204784G9 (Deleted by REV E).                                      | 11           |
| R56          | 3R77P363J                        | Composition: $36,000$ ohms $\pm 5\%$ , $1/2$ w.                                  | Q2               |               |   | and<br>C5       |                      | -80 PPM.  |                      |                               |   |              |               | TRANSISTORS   | Z353*         |                          | Z352 19B204784G10<br>Z353* 19B204784G11 (Added by REV E).                                      | 12           |
| R57          | 3R77P103K                        | Composition: 10,000 ohms $\pm 10\%$ , $1/2$ w.                                   |                  |               | RESISTORS   | C6              | 5496218P247          | Ceramic disc: 22 pf ±5%, 500 VDCW, temp coef          | FL5                  | 19B206692G1                   | Bandpass.   | Q341*<br>and | 19A116741P1   | Silicon, NPN.   |               |                          | CAPACITORS   | 13           |
| R58          | 3R77P913J                        | Composition: 91,000 ohms ±5%, 1/2 w.   | R1<br>thru       | 3R152P562J    | Composition: 5600 ohms ±5%, 1/4 w.  |                 | T 40000000100        | -80 PPM.  Ceramic, stand-off: 1000 pf +100% -0%, 500  |                      |                               | RESISTORS   | Q342*        |               | In 19E500873Gl and G3 of REV F and earlier:   | C7            | 54962:18 <b>P24</b> 8    | Ceramic disc: 24 pf ±5%, 500 VDCW, temp coef   | 14           |
| R59*         | 3R77P182J                        | Composition: 1800 ohms ±5%, 1/2 w.   | R4               | 0.015.001.04% | Composition: 0.1 megohm $\pm 10\%$ , $1/4$ w.   | C7<br>and<br>C8 | 5493392P107          | VDCW; sim to Allen-Bradley Type SS5D.                 | R8                   | 3R152P103K                    | Composition: 10,000 ohms ±10%, 1/4 w.   |              |               | In 19E500873G2 of REV G and earlier:  | and<br>C8     |                          | -80 PPM.   | 15           |
|              | 3R152P432J                       | In REV C and earlier:  Composition: 4300 ohms ±5%, 1/4 w.                        | R5<br>thru<br>R8 | 3R152P104K    | Composition: U.1 megonm ±10%, 1/4 w.  | C9              | 5491601 <b>P</b> 123 | Phenolic: 1.5 pf ±5%, 500 VDCW.                       | R14*                 | 3R152P752K                    | Composition: 7500 ohms ±10%, 1/4 w. Deleted by REV F in 19E500873Gl and G3, by REV G in G2. |              | 19A116203P2   | Silicon, NPN.   | C9            | 54962:18P244             | Ceramic disc: 15 pf ±5%, 500 VDCW, temp coef   | 16           |
| R60          | 3R77P432J                        | Composition: 4300 ohms ±5%, 1/2 w.   | R9               | 3R152P153J    | Composition: 15,000 ohms ±5%, 1/4 w.  | C10             | 5491601P117          | Phenolic: 0.68 pf ±5%, 500 VDCW.                      |                      |                               |   |              |               | RESISTORS   | 610           | 5.4060m cm0.43           | -80 PPM.   | 17           |
| R61          | 3R77P682K                        | Composition: 6800 ohms ±10%, 1/2 w.  | R10              | 3R152P101K    | Composition: 100 ohms ±10%, 1/4 w.  | C11             | 5491601P118          | Phenolic: 0.75 pf ±5%, 500 VDCW.                      | A406                 |                               | (See A364 and A365)   | R343<br>and  | 3R152P101K    | Composition: 100 ohms ±10%, 1/4 w.  | C12           | 54962018P241             | Ceramic disc: 10 pf ±5%, 500 VDCW, temp<br>coef -80 PPM.                                       | 18           |
|              |                                  |  | R11              | 3R152P102J    | Composition: 1000 ohms ±5%, 1/4 w.  | C13             | 5491601P137          | Phenolic: 0.91 pf ±5%, 500 VDCW.                      |                      |                               | CHASSIS AND RF ASSEMBLY   | R344         |               |   | C13           | 54962:18P237             | Ceramic disc: 6.0 pf ±5%, 500 VDCW, temp   | 19           |
|              |                                  |  | and<br>R12       |               |   | C14             | 5491601P114          | Phenolic: 0.51 pf ±5%, 500 VDCW.                      |                      |                               | 19E500873Gl thru G3   | R345         | 19A116278P444 | Metal film: 0.28 megohm $\pm 2\%$ , $1/2$ w.  | C14           | 54962:18P236             | Ceramic disc: 5.0 pf ±0.25 pf, 500 VDCW, temp  | 20           |
| RT1          | 5490828P22                       | Thermistor: 50,000 ohms $\pm 10\%$ , color code yellow; sim to Globar Type 763H. | R14              | 3R152P103J    | Composition: 10,000 ohms $\pm 5\%$ , 1/4 w.   | C15             | 5491601P115          | Phenolic: 0.56 pf ±5%, 500 VDCW.                      |                      |                               | CAPACITORS  | R346         | 3R78P390K     | Composition: 39 ohms ±10%, 1 w.   |               |                          | coef -80 PPM.  | 21           |
|              |                                  |  | R15              | 3R152P101K    | Composition: 100 ohms $\pm 10\%$ , $1/4$ w.   | C34             | 5491601P127          | Phenolic: 2.4 pf ±5%, 500 VDCW.                       | C349                 | 5491601P120                   | Phenolic: 1.0 pf ±5%, 500 VDCW.   |              |               |   | C15<br>and    | 54962:18P242             | Ceramic disc: 12 pf ±5%, 500 VDCW, temp<br>coef -80 PPM.                                       | 22           |
| XFL1         | 19A121920G3                      | Reed, mica-filled phen: 7 pins rated at 1 amp                                    | R19              | 3R152P360J    | Composition: 36 ohms ±5%, 1/4 w.  | C35             |                      |   | C350                 | 5491601P117                   | Phenolic: 0.68 pf ±5%, 500 VDCW.  | T341         | 19A116041P2   | Audio: 300 to 4000 Hz,  | C16           |                          |  | 23           |
| YLL          | 19412192003                      | at 500 VRMS with 4-1/2 inches of cable.  | R21              | 3R152P750J    | Composition: 75 ohms $\pm 5\%$ , $1/4$ w.   | C36             | 5491601P126          | Phenolic: 2.2 pf ±5%, 500 VDCW.                       | C351                 | 5491601P114                   | Phenolic: 0.51 pf ±5%, 500 VDCW.  |              |               | Pri: 1.00 chms ±15% DC res,<br>Sec 1: 1.23 chms ±10% DC res,<br>Sec 2: 10.5 chms ±15% DC res. |               | 5 403 Shares             | MISCELLANEOUS  | 24           |
| A352         |                                  | FIRST OSCILLATOR ASSEMBLY  |                  |               |   |                 |                      | DIODES AND RECTIFIERS                                 | C358<br>thru         | 5493392P7                     | Ceramic feed-thru: 1000 pf +100% -0%, 500 VDCW; sim to Allen-Bradley Type FA5C.             |              |               | Sec 2: 10.5 onms 115% bc res.   |               | 54917798P1<br>54917798P4 | Tuning slug. (Used in Z350). Tuning slug. (Used in Z351 and Z353).                             | 25           |
| thru<br>A357 |                                  | A352 19B204419G13<br>A353 19B204419G16   | RT1              | 19B209284P5   | Disc: 43 ohms res nominal at 25°C, color code   | CR1             | 4038056P1            | Germanium.  | C363                 |                               |   |              |               | TERMINAL BOARDS   |               | 54917798P4<br>54917798P5 | Tuning slug. (Used in Z352).   | 26           |
|              |                                  | A354 19B204419G14<br>A355 19B204419G17   | thru<br>RT4      |               | green.  |                 |                      | INDUCTORS   | C385                 | 7774750P4                     | Ceramic disc: .001 µf +100% -0%, 500 VDCW.  | TB1          | 7487424P26    | Miniature, phen: 6 terminals.   |               | 0451 % 5625              | luning Sing. (osed in 2002).   | 28           |
|              |                                  | A356 19B204419G15<br>A357 19B204419G18   |                  |               | TRANSFORMERS  | L1              |                      | (Part of Tl and T4).                                  | C387<br>and          | 5494481P12                    | Ceramic disc: 1000 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.                           |              |               |   |               |                          |  | 29           |
|              |                                  | CAPACITORS   | T3               |               | COIL ASSEMBLY<br>T3 19B205416G1   | 10              |                      | (Part of T2 and T5).                                  | C388                 |                               | DIODES AND RECTIFIERS   | W442         | 19B205634G6   | Coaxial: approx 5 inches long,  |               |                          | HARNESS ASSEMBLY<br>19E500873G14   | 30           |
|              | 5494481P112                      | Ceramic disc: 1000 pf ±10%, 1000 VDCW; sim to                                    | T4               |               | T4 19B205416G2  | 1.3             |                      | (Part of T3 and T6).                                  | CR1*                 | 19A116062P2                   | Thyrector. Deleted by REV E in 19E500873G1 and  | W443         | 19B205634G3   | Coaxial: approx 5 inches long.  |               |                          | (Include C385, C387, C388, J442, J443, P301-P304, P307-P313, P315-P317, P319, P320, P322-P327, |              |
| thru         | J454401F112                      | RMC Type JF Discap.  | 1                |               | CAPACITORS  |                 |                      |   |                      | 10.112.00                     | G3, by REV F in G2.   |              |               | TUNED CIRCUITS  |               |                          | R345, R346, T341, TB1)   |              |
| C5           | 5496219P751                      | Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef                                     | C34              | 5496218P253   | Ceramic disc: 39 pf ±5%, 500 VDCW, temp coef  |                 |                      | RESISTORS   |                      |                               | JACKS AND RECEPTACLES   |              |               | TORED CIRCUITS  |               |                          |  |              |
| thru<br>C8   |                                  | -750 PPM.  |                  |               | -80 PPM.  | R1              | 3R152P473K           | Composition: 47,000 ohms ±10%, 1/4 w.                 | J442                 | 19 <b>B2</b> 05689 <b>G</b> 2 | Connector: 18 contacts.   | Z341<br>thru |               | COIL ASSEMBLY<br>Z341 19B204786G4   |               |                          | CHANNEL GUARD MODIFICATION KIT<br>19A127178G1  |              |
| C9           | 5491271P106                      | Variable, subminiature: approx 2.1-12.7 pf,                                      | C35              | 5496218P249   | Ceramic disc: 27 pf ±5%, 500 VDCW, temp coef -80 PPM.                                     |                 |                      | TRANSFORMERS  | J443                 | 19C303426G1                   | Connector: 20 pin contacts.   | A343         |               | Z342 19B204786G5<br>Z343 19B204786G6  |               |                          | (Used with A350)   |              |
| thru<br>Cl2  |                                  | 750 v peák; sim to EF Johnson 189.   |                  |               | INDUCTORS   | T1              | 19B205325G2          | Coil, includes tuning slug 5491798P4.                 |                      |                               |   |              |               |   |               |                          | MISCELLANEOUS  |              |
| C13<br>thru  | 5496219P40                       | Ceramic disc: 9 pf ±0.25 pf, 500 VDCW, temp coef 0 PPM.                          | L4               | 19A121464P2   | Coil.   | T2<br>and       | 19B205325G1          | Coil, includes tuning slug 5491798P4.                 |                      |                               | COIL ASSEMBLY   |              |               |   |               | 19B2116176G1             | Harness (Encoder/Decoder). Includes:   |              |
| C16          |                                  |  |                  | 10,1121       |   | Т3              |                      |   | L341<br>thru<br>L345 |                               | L341 19B204820G5<br>L342 19B204820G6  | C1           | 5496218P254   | Ceramic disc: 43 pf ±5%, 500 VDCW, temp coef -80 PPM.   | P314          | 4029840P2                | Contact, electrical; sim to Amp 42827-2.   |              |
| C17<br>thru  | 19C300685P93                     | Ceramic disc: 5 pf ±0.1 pf, 500 VDCW, temp coef 0 PPM.                           |                  |               | MISCELLANEOUS   | T4              | 19B205325G2          | Coil, includes tuning slug 5491798P4.                 | 1545                 |                               | L343 19B204820G1<br>L344 19B204820G2  | C2           | 5496218P250   | Ceramic disc: 30 pf ±5%, 500 VDCW, temp coef -80 PPM.   | P318          | 4029840P2                | Contact, electrical; sim to Amp 42827-2.   |              |
| C20          |                                  | 000 vs +500 VDCW +500 ocs  |                  | 5491798P5     | Tuning slug.  | T5<br>and       | 19B205325G1          | Coil, includes tuning slug 5491798P4.                 |                      |                               | L345 19B204820G3  | СЗ           | 5496218P245   | Ceramic disc: 18 pf ±5%, 500 VDCW, temp coef  | P321          | 40298840P2               | Contact, electrical; sim to Amp 42827-2.   |              |
| C21          | 5496219P771                      | Ceramic disc: 220 pf ±5%, 500 VDCW, temp coef<br>-750 PPM.                       |                  |               |   | Т6              |                      |   |                      |                               |   |              |               | -80 PPM.  | P328<br>thru  | 40298840P2               | Contact, electrical; sim to Amp 42827-2.   | <u>III</u> º |
| C22          | 5496219P773                      | Ceramic disc: 270 pf ±5%, 500 VDCW, temp coef -750 PPM.                          | XY1<br>thru      |               | Refer to Mechanical Parts (RC-1692).  | A402            |                      | TONE REJECT FILTER<br>19C311797G2                     | C341                 | 19B209159P3                   | Variable, subminiature: approx 1.70-6.9 pf, 750 v peak; sim to EF Johnson 189.              | C4           | 5494481P14    | Ceramic disc: 2000 pf $\pm 10\%$ , 500 VDCW; sim to RMC Type JF Discap.                       | P335          |                          |  |              |
| C23          | 5494481P114                      | Ceramic disc: 2000 pf ±10%, 1000 VDCW; sim to                                    | XY4              |               |   |                 |                      |   | and<br>C342          |                               | 750 V peak, Sim to Er Johnson 165.  |              |               | MISCELLANEOUS   |               |                          | CHANNEL GUARD MODIFICATION KIT<br>19A127178G2  |              |
| 1 025        | 0.01.01.1                        | RMC Type JF Discap.  |                  |               |   |                 |                      |   |                      |                               | INDICATING DEVICES  |              | 5491798P1     | Tuning slug. (Used in Z341).  |               |                          | (Used with A402)   |              |
| C26<br>thru  | 5494481P112                      | Ceramic disc: 1000 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.                |                  |               | NOTE: When reordering give GE Part No. and specify exact freq needed.                     | C26             | 19A116080P206        | Polyester: 0.068 µf ±5%, 50 VDCW.                     | DS301                | 19 <b>B2</b> 09067 <b>P1</b>  | Lamp, glow: 0.3 ma; sim to GE NE-2T.  |              | 5491798P4     | Tuning slug. (Used in Z342).  |               |                          | MISCELLANEOUS  |              |
| C28          |                                  | 1000 S 1100 1000 ITM   |                  |               | 25-42 MHz crystal freq = (OF +5.30 MHz) + 3.  | C27<br>and      | 19A116080P210        | Polyester: 0.33 μf ±5%, 50 VDCW.                      | L346                 |                               | COIL ASSEMBLY   |              | 5491798P5     | Tuning slug. (Used in Z343).  |               | 19B2#6177G1              | Harness (Tone Reject Filter), Includes:  |              |
| C31          | 5494481P112                      | Ceramic disc: 1000 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.                |                  |               | 42-50 MHz crystal freq = (OF -5.30 MHz) ; 3.  | C28<br>C29*     | 19Al16080P205        | Polyester: 0.047 µf ±5%, 50 VDCW.                     |                      |                               | 19B204820G4   |              |               |   | P321          | 4029i840P2               | Contact, electrical; sim to Amp 42827-2.   |              |
| C45          | 5490008P35                       | Silver mica: 220 pf ±5%, 500 VDCW.   | Y1               | 19B206576Pl   | Quartz: freq range 10086.666 to 12766.666 KHz, temp range -30°C to +85°C. (25-33 MHz).    | C29+            | 194110080F203        | Earlier than REV A:                                   |                      |                               |   | Z347<br>thru |               | COIL ASSEMBLY<br>Z347 19B204767G1   | P330          | 4029i840P2               | Contact, electrical; sim to Amp 42827-2.   |              |
| C46          | 5496219P563                      | Ceramic disc: 100 pf ±5%, 500 VDCW, temp coef -330 PPM.                          | thru<br>Y4       |               |   |                 | 19B209243P107        | Polyester: 0.1 µf ±10%, 50 VDCW.                      | C342*                | 19B209159P4                   | Variable, subminiature: approx 1.80-8.3 pf, 650 v peak; sim to EF Johnson 189.              | Z349         |               | Z348 19B204767G2<br>Z349 19B204767G3  | P332          | 4029+840P2               | Contact, electrical; sim to Amp 42827-2.   |              |
|              |                                  |  | Yl<br>thru       | 19B206576P2   | Quartz: freq range 12766.667 to 15766.666 KHz,<br>temp range -30°C to +85°C. (33-42 MHz). |                 |                      |   |                      |                               | In REV H and earlier:   |              |               |   |               |                          | MECHANICAL PARTS   |              |
|              |                                  | DIODES AND RECTIFIERS  | Y4               |               |   |                 |                      | JACKS AND RECEPTACLES                                 |                      | 19 <b>B2</b> 09159P3          | Variable, subminiature: approx 1.70-6.9 pf,   | C1           | 5496218P254   | Ceramic disc: 43 pf ±5%, 500 VDCW, temp coef  |               |                          | (SEE RC-1692)  |              |
| CR1<br>thru  | 19All5603Pl                      | Silicon.   | Yl<br>thru       | 19B206576P3   | Quartz: freq range 12233.333 to 16233.333 KHz, temp range -30°C to +85°C. (42-54 MHz).    | J6<br>and       | 4033513P4            | Contact, electrical; sim to Bead Chain L93-3.         |                      | 13520310370                   | 750 v peak; sim to EF Johnson 189.  |              | 34302107204   | -80 PPM.  | 1             | 19B2i04583G3             | Hinge.   |              |
| CR4          |                                  |  | Y4               |               |   | J7              |                      |   |                      |                               |   | C2           | 5496218P250   | Ceramic disc: 30 pf ±5%, 500 VDCW, temp coef -80 PPM.   | 2             | 19B2:16727Pl             | Support, (Used with Q341 and Q342).  |              |
|              |                                  |  |                  |               |   |                 |                      |   | P301                 | 4029840P2                     | Contact, electrical; sim to Amp 42827-2.  |              |               |   | 3             | 19Al.16023P2             | Plate, insulated. (Used with Q341 and Q342).   |              |
|              |                                  |  |                  |               |   |                 |                      |   | thru<br>P311         |                               |   |              |               |   |               |                          |  |              |
|              |                                  |  |                  |               |   |                 |                      |   | P312                 | 4029840P3                     | Contact, electrical; sim to Amp 42101-2.  |              |               |   |               |                          |  |              |
|              | 1                                |  |                  | 1             |   |                 |                      |   | P313                 | 4029840P2                     | Contact, electrical; sim to Amp 42827-2.  | 11           |               |   | 1             |                          |  |              |

P315 thru P317

Contact, electrical; sim to Amp 42827-2.



# Retainer, transistor. (Used with Q1 on A341). 7162414P1 19B204917P1 Support. 123 4

# **PRODUCTION CHANGES**

Changes in the equipment to improve performance or to simplify circuits are identified by a "Revision Letter", which is stamped after the model number of the unit. The revision stamped on the unit includes all previous revisions. Refer to the Parts List for descriptions of parts affected by these revisions.

- REV. A 2nd Mixer A347 (19B216119-G1) Channel Guard Encoder/Decoder Model 4EK16A10 1st Osc/Mult A354-A357
- REV. C 1st Osc/Mult A352 & A353 <u>IF-Audio & Squelch A348</u> (19D413129-G1)
- REV. D Chassis & RF Assembly (19E500873-G1 thru G3) These revisions incorporated into initial shipment.
- REV. D IF Audio & Squelch Board A348 (19D413129-G1) To improve receiver frequency response. Changed R30 and R78.
- REV. B Channel Guard Encoder/Decoder Model 4EK16A10 To increase stop-band attenuation. Changed R8.
- REV. C Channel Guard Encoder/Decoder Model 4EK16Al0 REV. A Tone Reject Filter 19C311797-G2
- To optimize the frequency response. Changed C29.
- REV. D Channel Guard Encoder/Decoder Model 4EK16A10 REV. B Tone Reject Filter 19C311797-G2 To prevent excessive roll-off at 300 Hertz. Changed R59.
- REV. E Chassis & RF Assembly (19E500873-G2)

  To improve sensitivity. Changed Z351 to Z353.
- IF Audio & Squelch Board A348 (19D413129-G1) REV. E - To compensate for vendor change. Changed C26.
- REV. F To improve squelch action. Changed R53.

- REV. E Chassis & RF Assembly (19E500873G1&3) To remove unnecessary protection. Deleted CR1.
- REV. F Chassis & RF Assembly (19E500873-G2) To remove unnecessary protection. Deleted CR1.
- REV. F Chassis & RF Assembly (19E500873G1 & 2)
- To improve match. Deleted R14. REV. H - IF Audio & Squelch Board A348 (19D413129G1)
- To insure squelch action at -30°C. Changed Q10.
- REV. J To increase PA bias current. Changed R40.
- REV. K To improve stability to Audio output.
  Added R85.
- REV. L To improve frequency response. Deleted R85 and changed C40.
- REV. G Chassis & RF Assembly (19E500873G1 & G3
- REV. H Chassis & RF Assembly (19E500873G2)
- To incorporate new transistors. Changed Q341 and Q342.
- REV. M IF Audio & Squelch Board A348 (19D413129G1) To improve Audio quality, Changed R80.
- REV. N To improve frequency response. Changed C26.
- REV. P To improve stability. Changed Q5.
- REV. H Chassis & RF Assembly (19E501873G1 & 3)
- REV. J Chassis & RF Assembly (19E500873G2)

  To incorporate new transistor. Changed Q2 in 1st RF Amp
  A341 and Q1 in 1st Mixer (A345)
- REV. J Chassis & RF Assembly (19E500873G3) To improve tuning range of 1st RF stage. Changed C342.

END OF DOCUMENT